

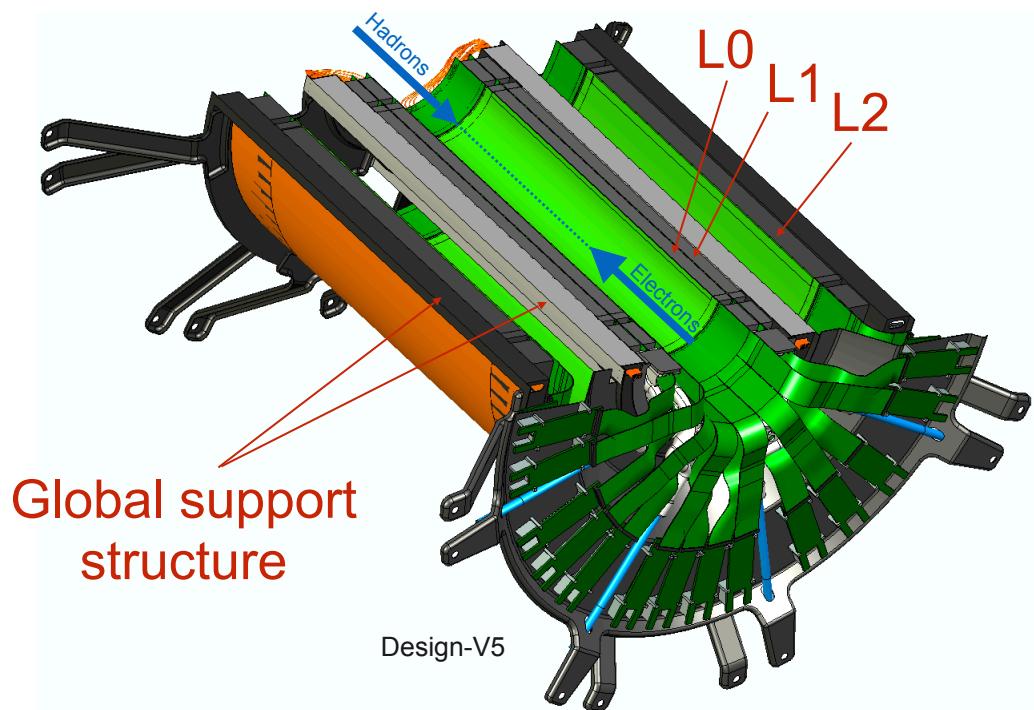


# Progress on SVT IB prototyping

On behalf of INFN teams  
(Bari, Padova, Pavia, Trento, Trieste)

## Basic ingredients:

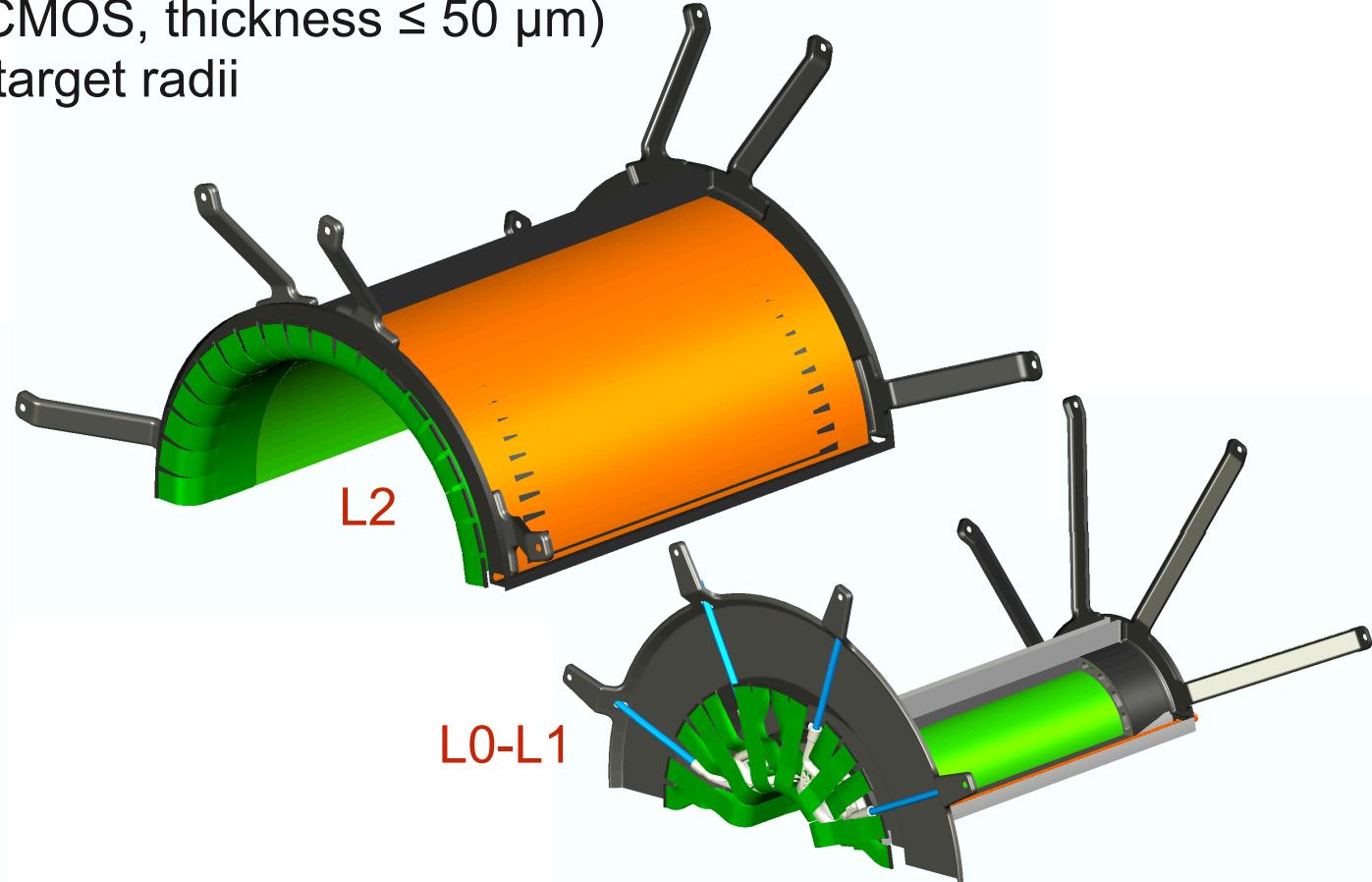
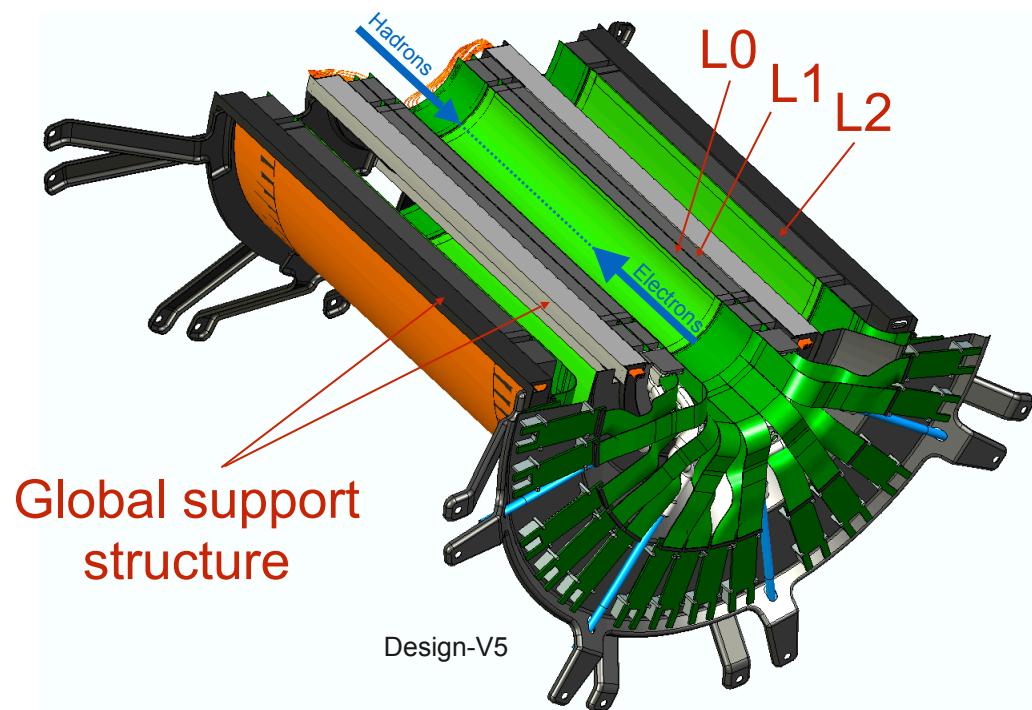
- Wafer-scale MAPS chips (ITS3 65 nm CMOS, thickness  $\leq 50 \mu\text{m}$ )
- Chips bent in semi-cylindrical shape at target radii
- Ultra-light carbon foam/fiber structures
- Air cooling



Layer	Radii (mm)	Single sensor area (mm <sup>2</sup> )	# of sensors for a half-layer
L0	38	266 x 58.7	2
L1	50	266 x 78.3	2
L2	126	266 x 97.8	4

## Basic ingredients:

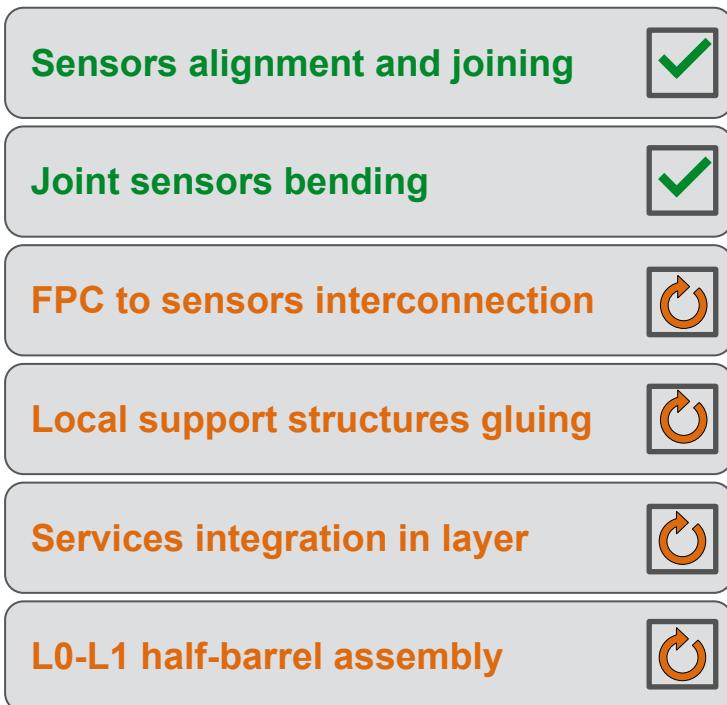
- Wafer-scale MAPS chips (ITS3 65 nm CMOS, thickness  $\leq 50 \mu\text{m}$ )
- Chips bent in semi-cylindrical shape at target radii
- Ultra-light carbon foam/fiber structures
- Air cooling



- L0-L1 half-barrel and L2 layer can be produced separately and integrated together in later stage

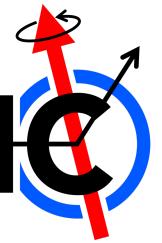
# Progress on SVT IB prototyping

## L0-L1 half-barrel assembly procedure



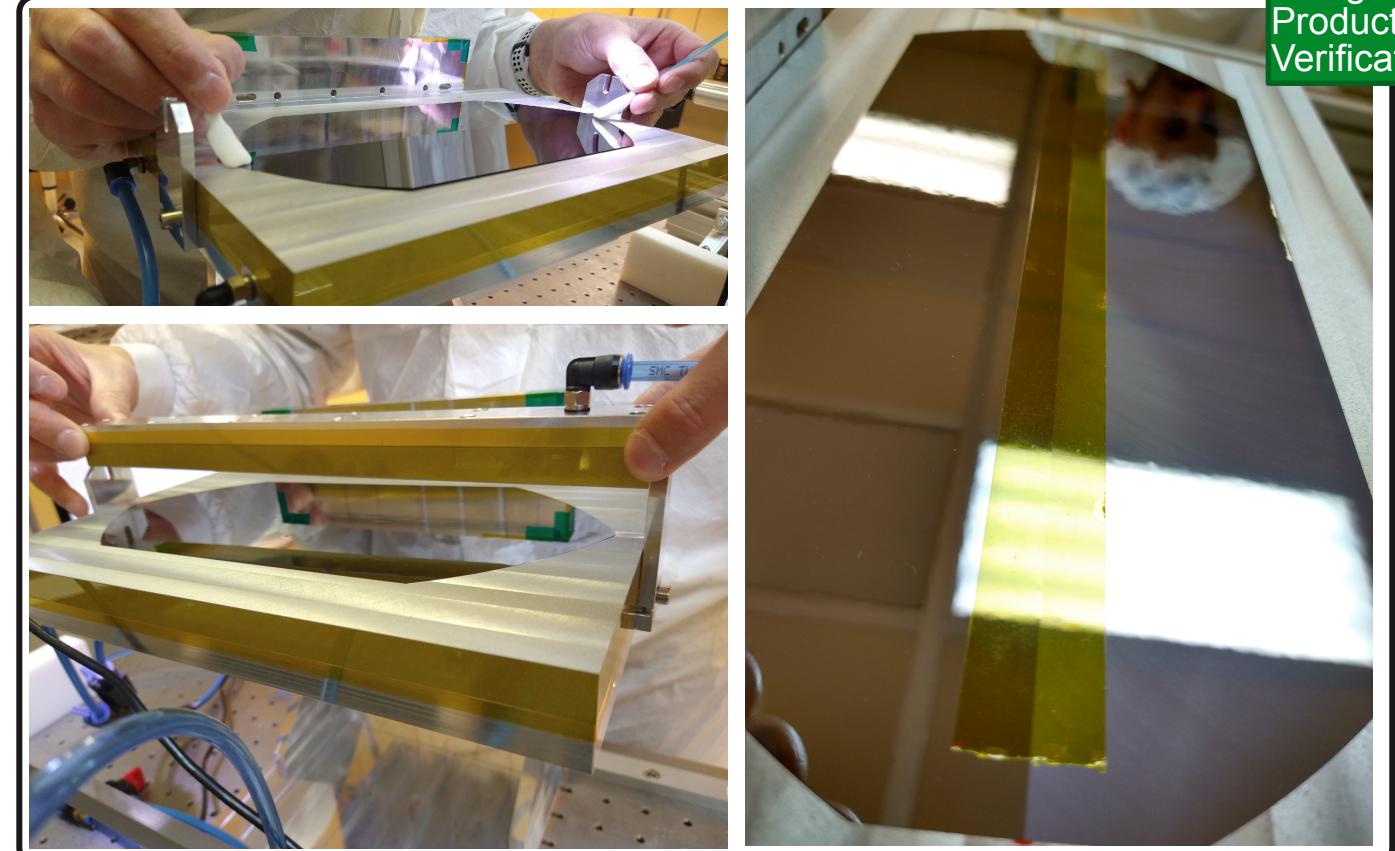
# Progress on SVT IB prototyping

## L0-L1 half-barrel assembly procedure



Design   
Production   
Verification

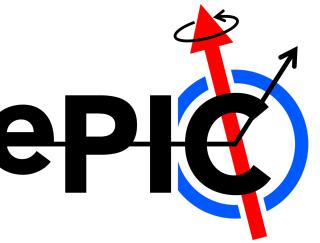
- Sensors alignment and joining 
- Joint sensors bending 
- FPC to sensors interconnection 
- Local support structures gluing 
- Services integration in layer 
- L0-L1 half-barrel assembly 



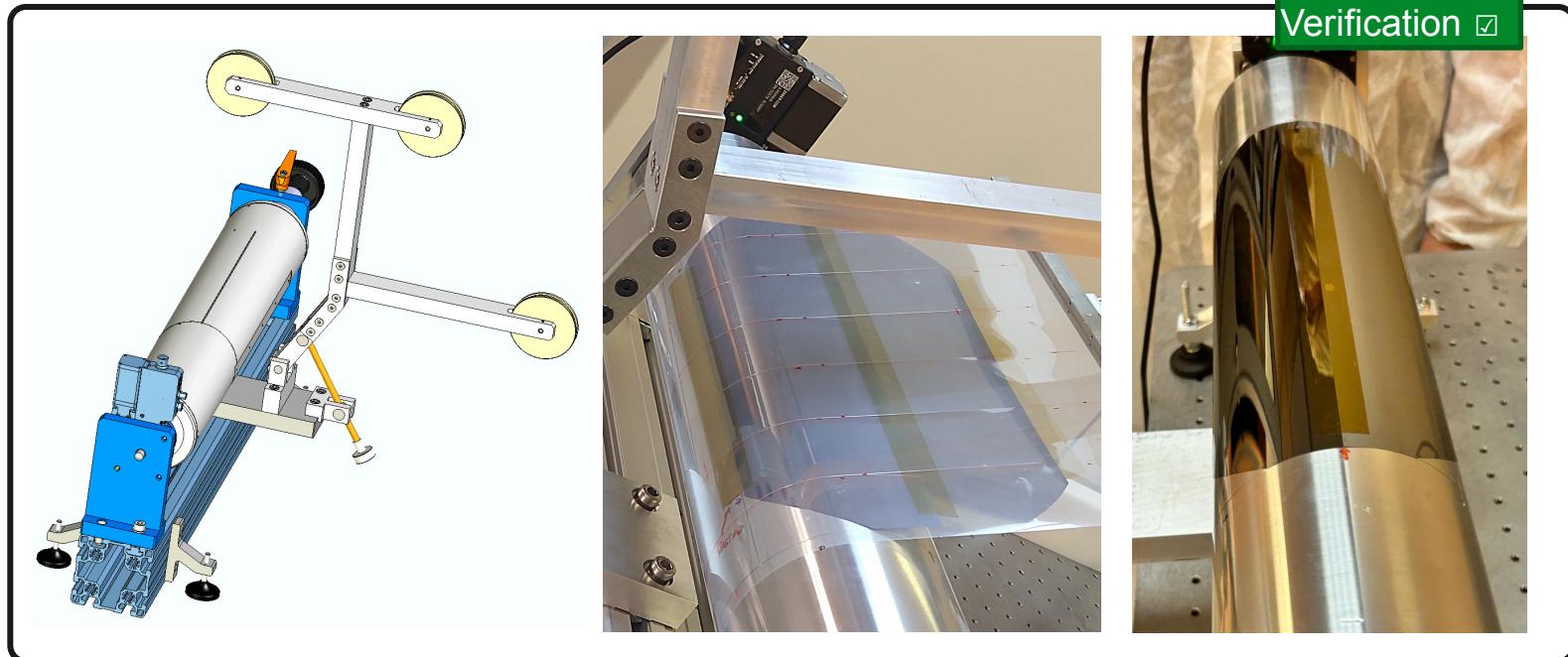
Few tens micron precision reached targeting  
50  $\mu\text{m}$  pitch between the two sensors

# Progress on SVT IB prototyping

## L0-L1 half-barrel assembly procedure



- Sensors alignment and joining** 
- Joint sensors bending** 
- FPC to sensors interconnection** 
- Local support structures gluing** 
- Services integration in layer** 
- L0-L1 half-barrel assembly** 

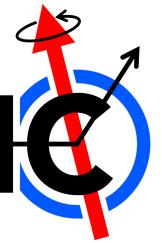


Design   
Production   
Verification

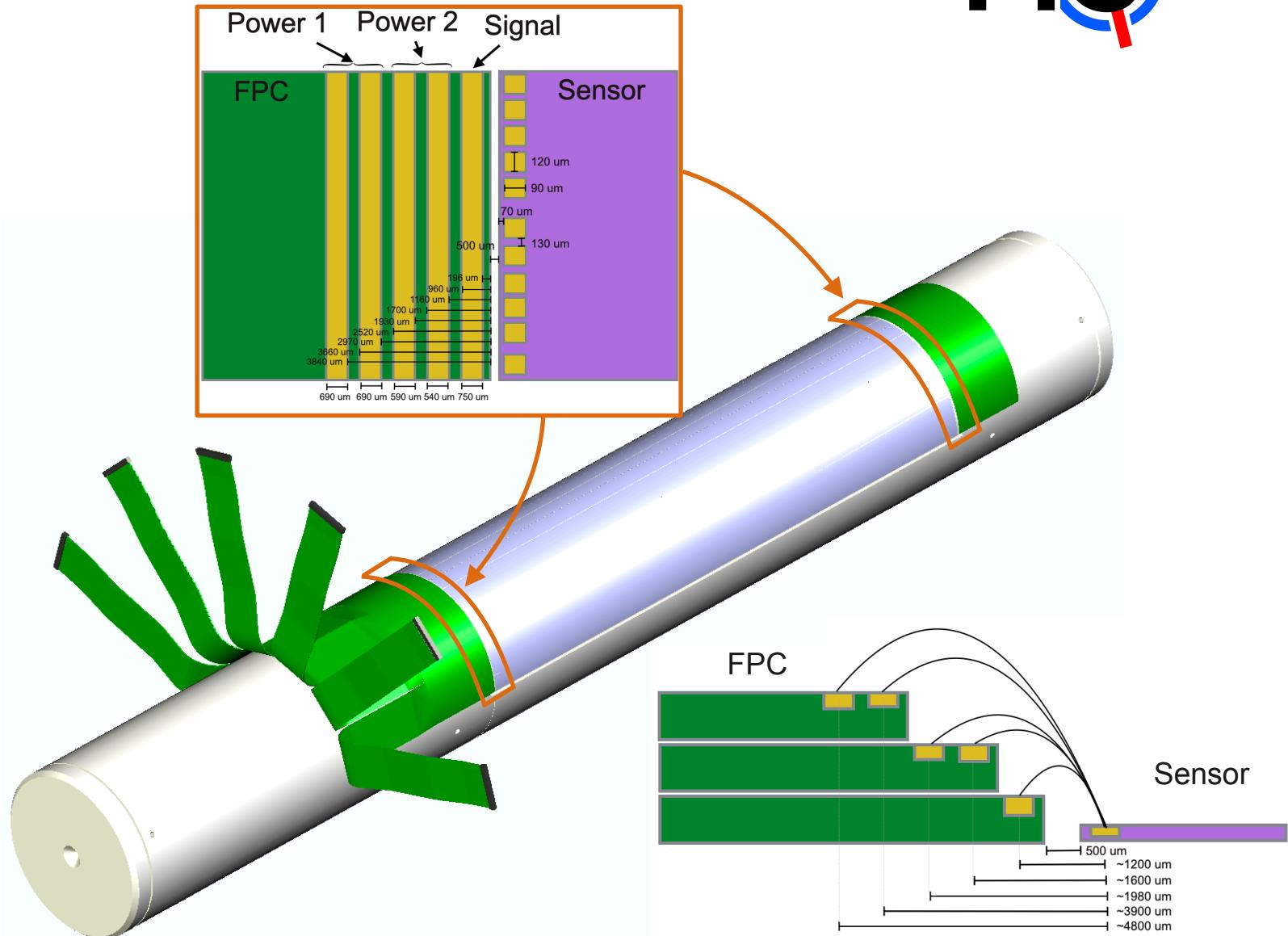
Double sensors bending mastered for L0 and L1

# Progress on SVT IB prototyping

## L0-L1 half-barrel assembly procedure



- Sensors alignment and joining 
- Joint sensors bending 
- FPC to sensors interconnection 
- Local support structures gluing 
- Services integration in layer 
- L0-L1 half-barrel assembly 

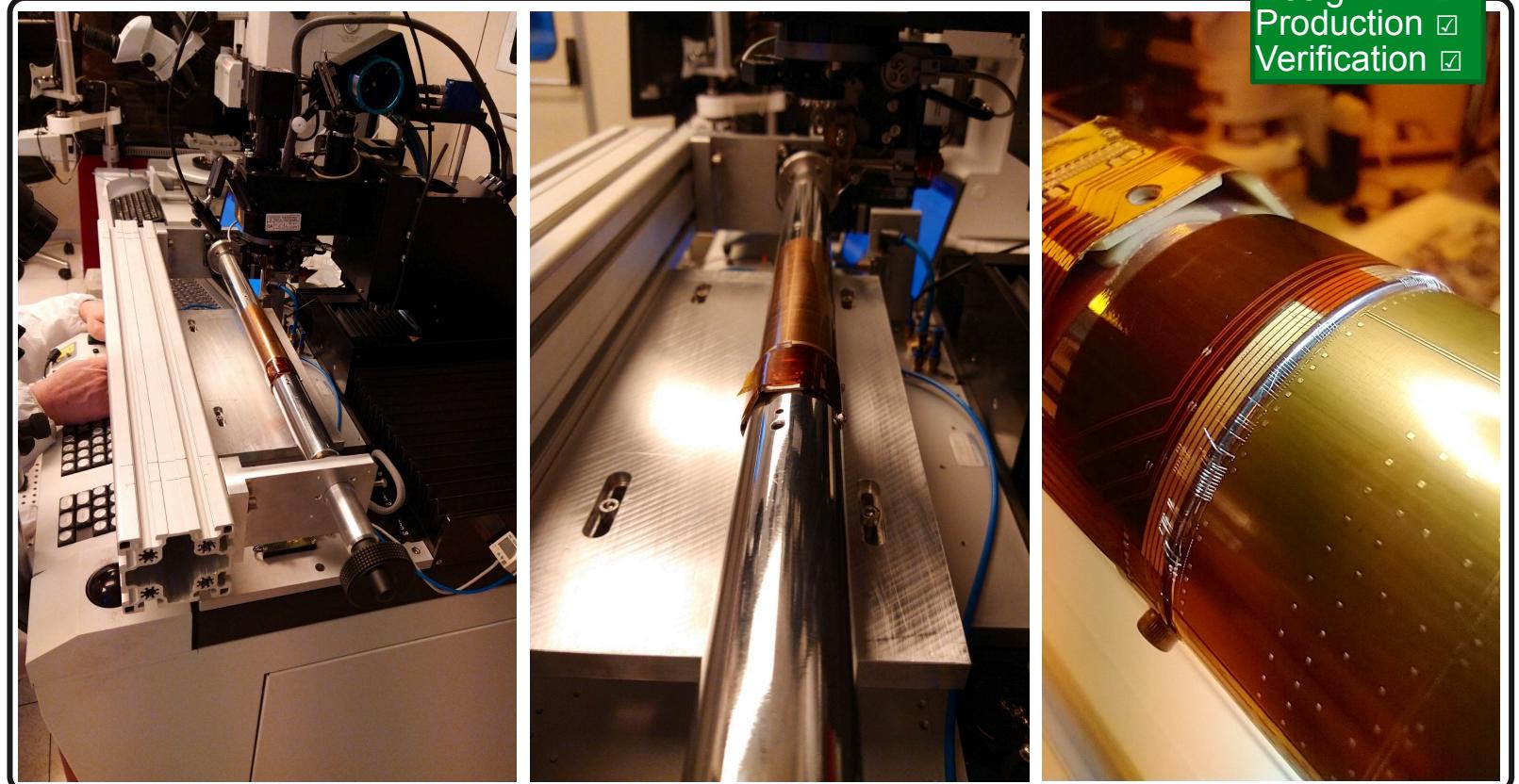


# Progress on SVT IB prototyping

## L0-L1 half-barrel assembly procedure



- Sensors alignment and joining** 
- Joint sensors bending** 
- FPC to sensors interconnection** 
- Local support structures gluing** 
- Services integration in layer** 
- L0-L1 half-barrel assembly** 



Bending tool used to place the setup under wire-bonding machine  
(Pictures from ITS3-SuperALPIDE exercise)

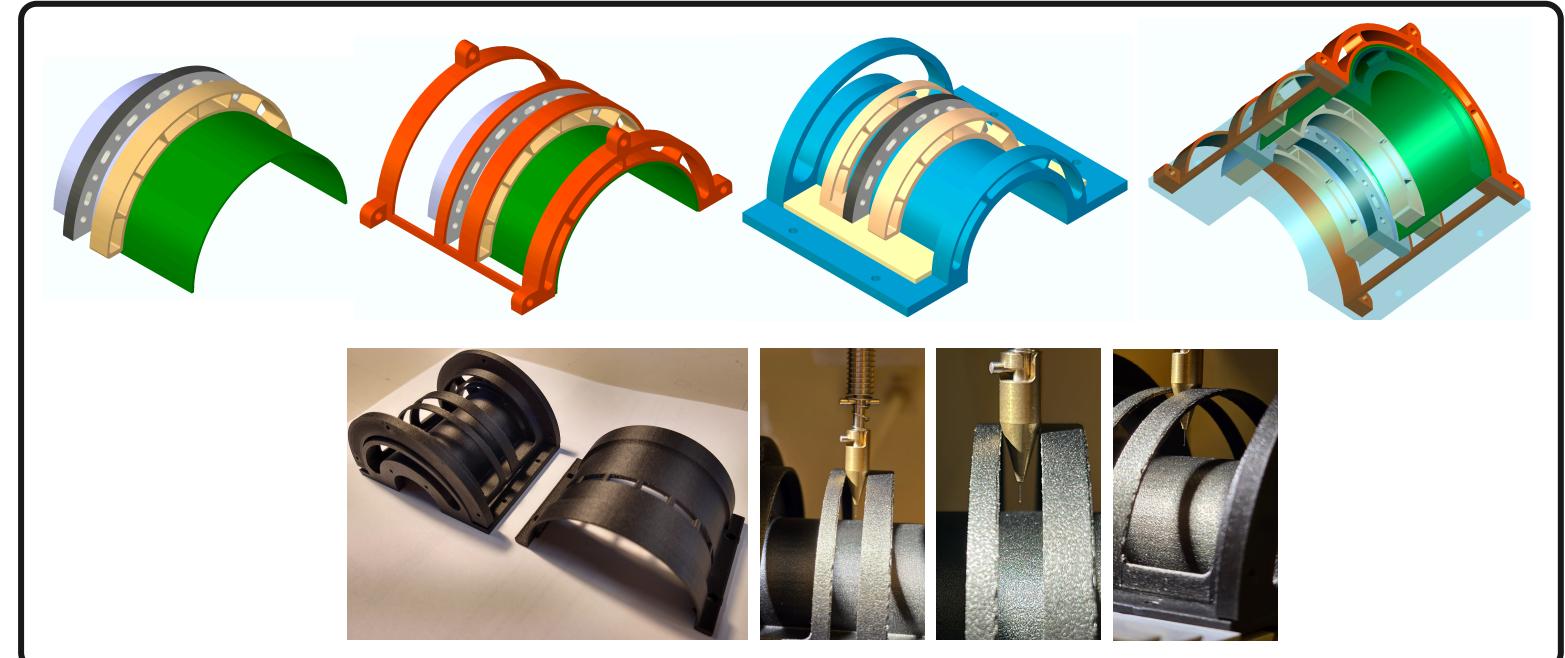
# Progress on SVT IB prototyping

## L0-L1 half-barrel assembly procedure



- Sensors alignment and joining 
- Joint sensors bending 
- FPC to sensors interconnection 
- Local support structures gluing 
- Services integration in layer 
- L0-L1 half-barrel assembly 

- Definition of best loop shapes and semi-automatic procedure for wire-bonding over bent surface
- Assessment of wire-bond pull-force variation following extended air-flow exposure
- Done in the context of ITS3 but valid for SVT-IB

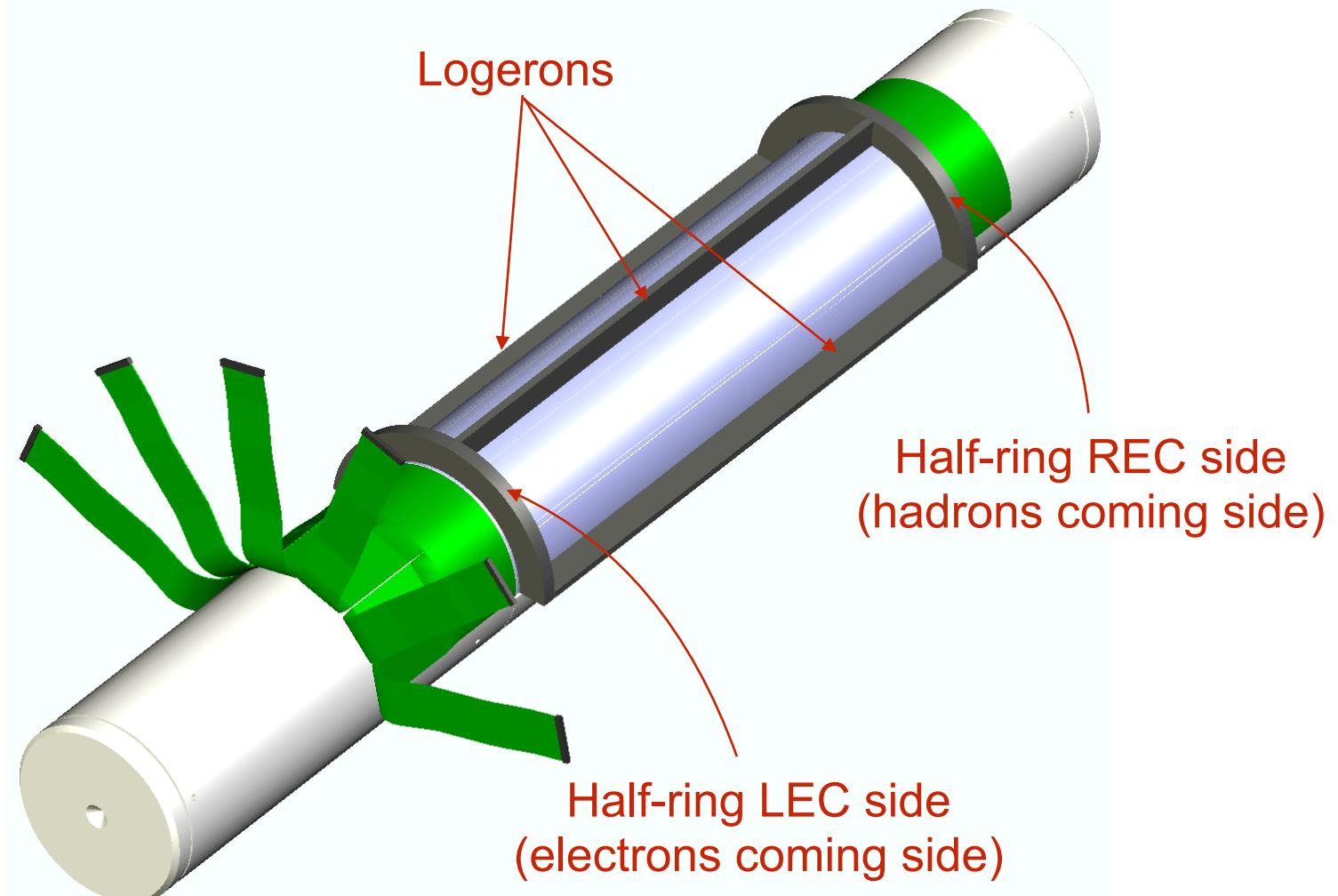


# Progress on SVT IB prototyping

## L0-L1 half-barrel assembly procedure

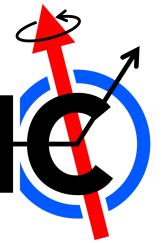


- Sensors alignment and joining
- Joint sensors bending
- FPC to sensors interconnection
- Local support structures gluing
- Services integration in layer
- L0-L1 half-barrel assembly

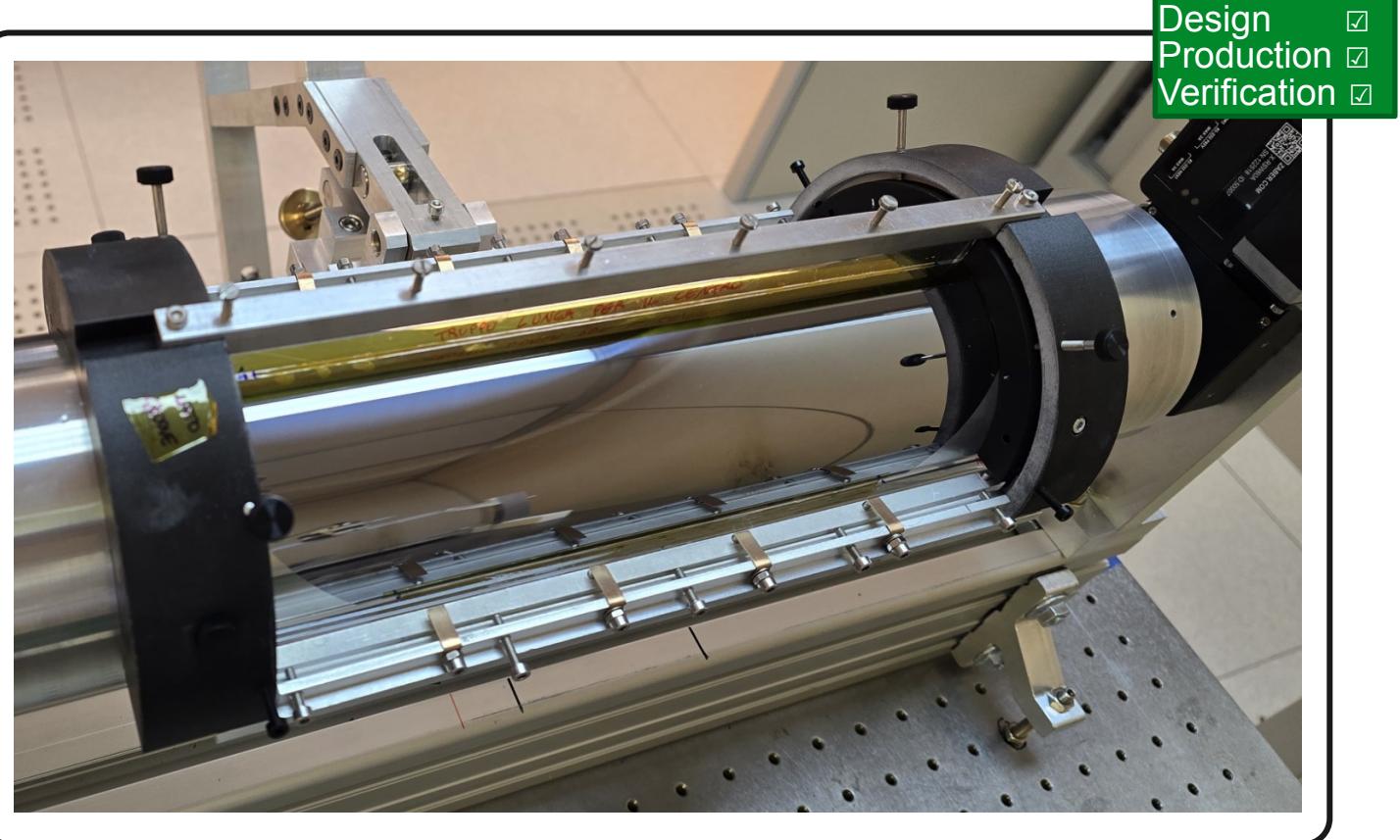


# Progress on SVT IB prototyping

## L0-L1 half-barrel assembly procedure



- Sensors alignment and joining** 
- Joint sensors bending** 
- FPC to sensors interconnection** 
- Local support structures gluing** 
- Services integration in layer** 
- L0-L1 half-barrel assembly** 

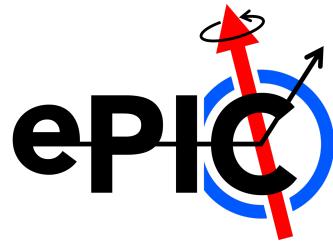


Design   
Production   
Verification

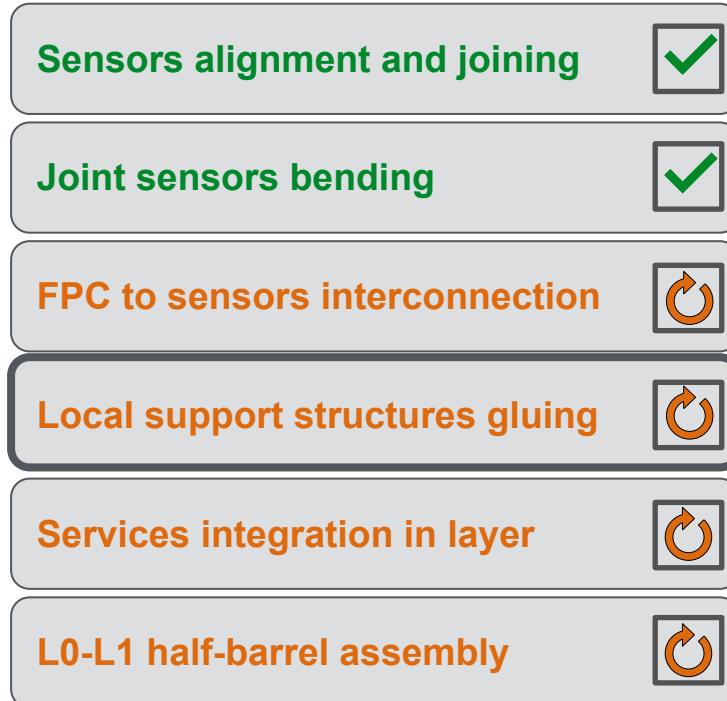
- Proof of principle → DONE!
- Tool rapidly evolving toward final requirements

# Progress on SVT IB prototyping

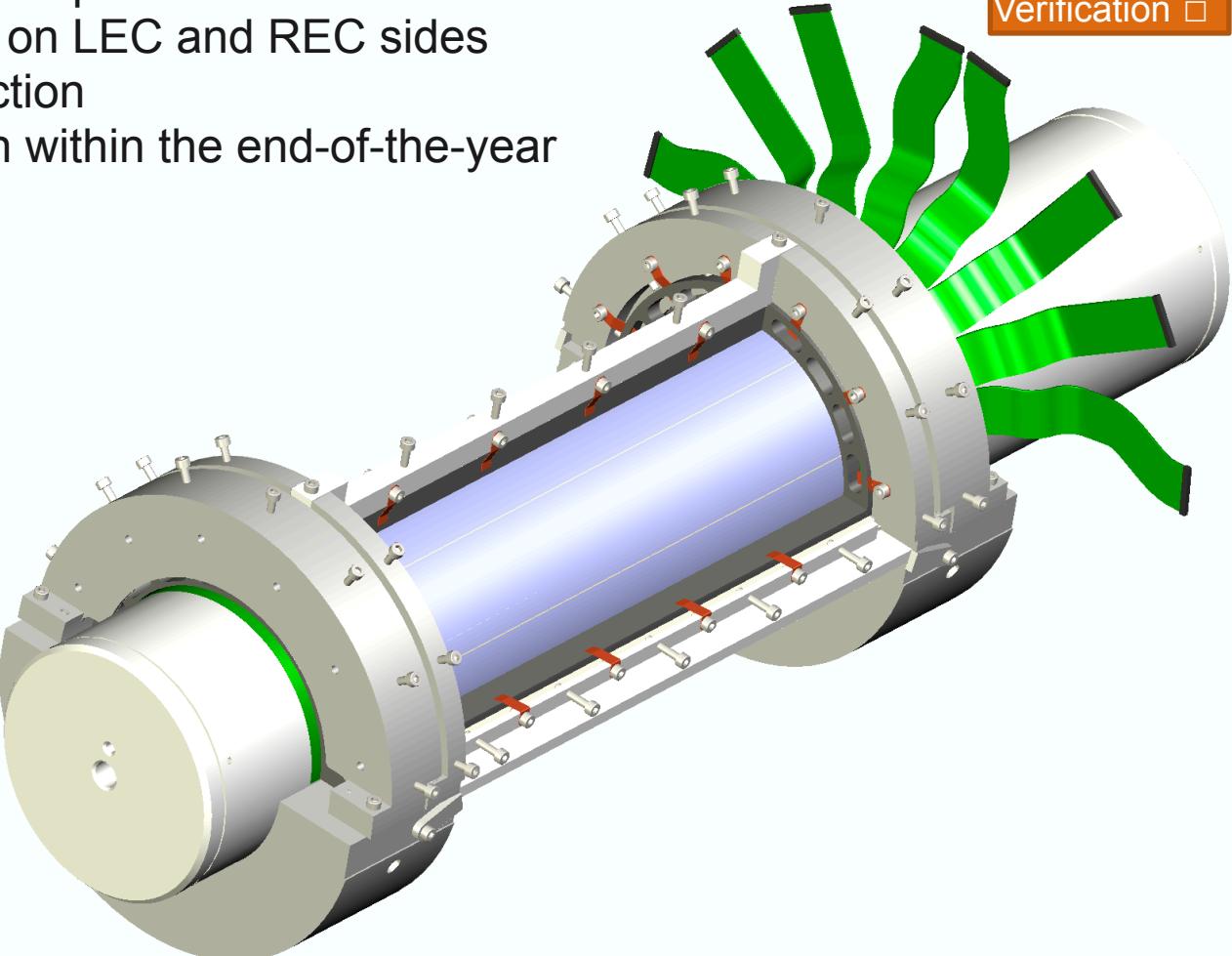
## L0-L1 half-barrel assembly procedure



Design   
Production   
Verification



- New design compatible with FPC and wire-bonding on LEC and REC sides
- Under production  
→ completion within the end-of-the-year



# Progress on SVT IB prototyping

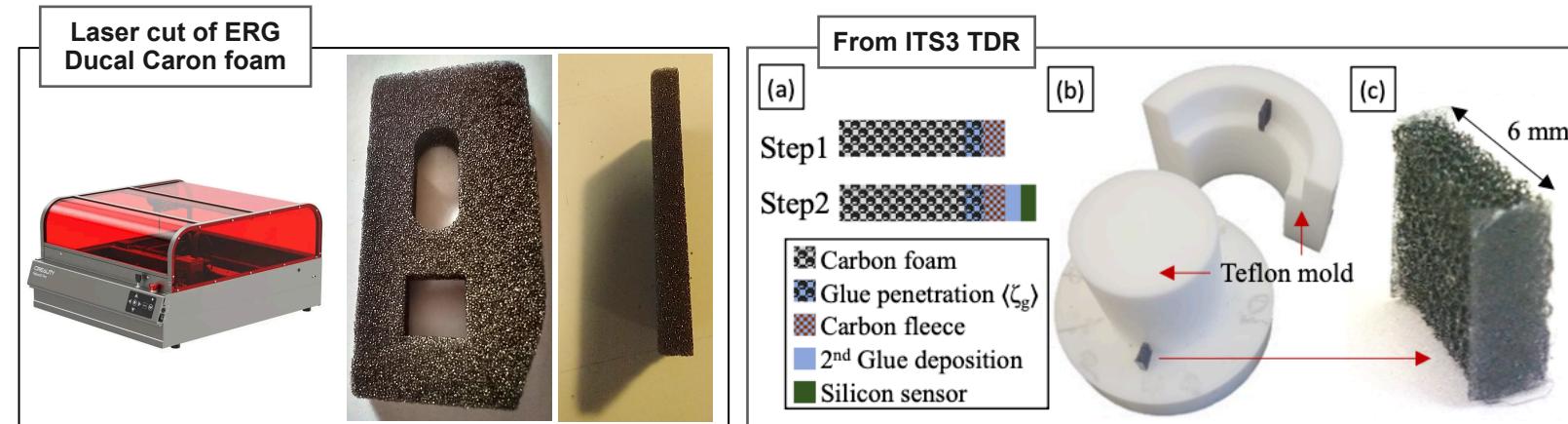
## L0-L1 half-barrel assembly procedure



- Sensors alignment and joining**
- Joint sensors bending**
- FPC to sensors interconnection**
- Local support structures gluing**
- Services integration in layer**
- L0-L1 half-barrel assembly**

### Local Support Structures in carbon foam:

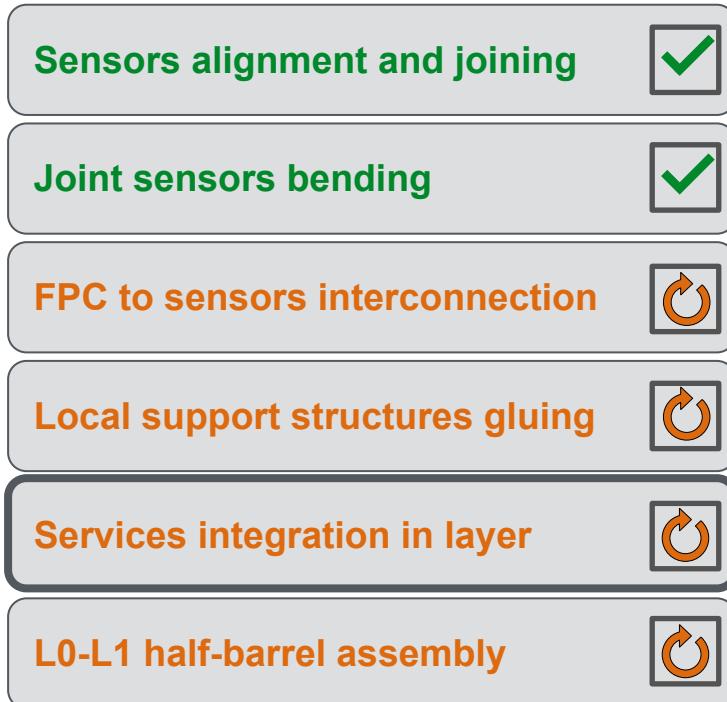
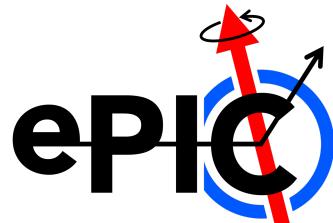
- Low density (ERG Duocel) for longerons and half-ring on REC side, while high density (high heat capacity, K9 Allcomp) for half-ring on LEC side
- Alternative materials under evaluation for the half-ring on LEC:
  - C-Foam HTC ( $\sim 100$  W/mK)
  - Aluminum → Chiara Bonini presentation later



- Shaping currently done via mechanical cut → Alternative procedure using laser cut (requiring thin foil, up to 6 mm, for efficient cut)
- Tooling for gluing of interface between carbon foam and sensor (carbon fleece) under design

# Progress on SVT IB prototyping

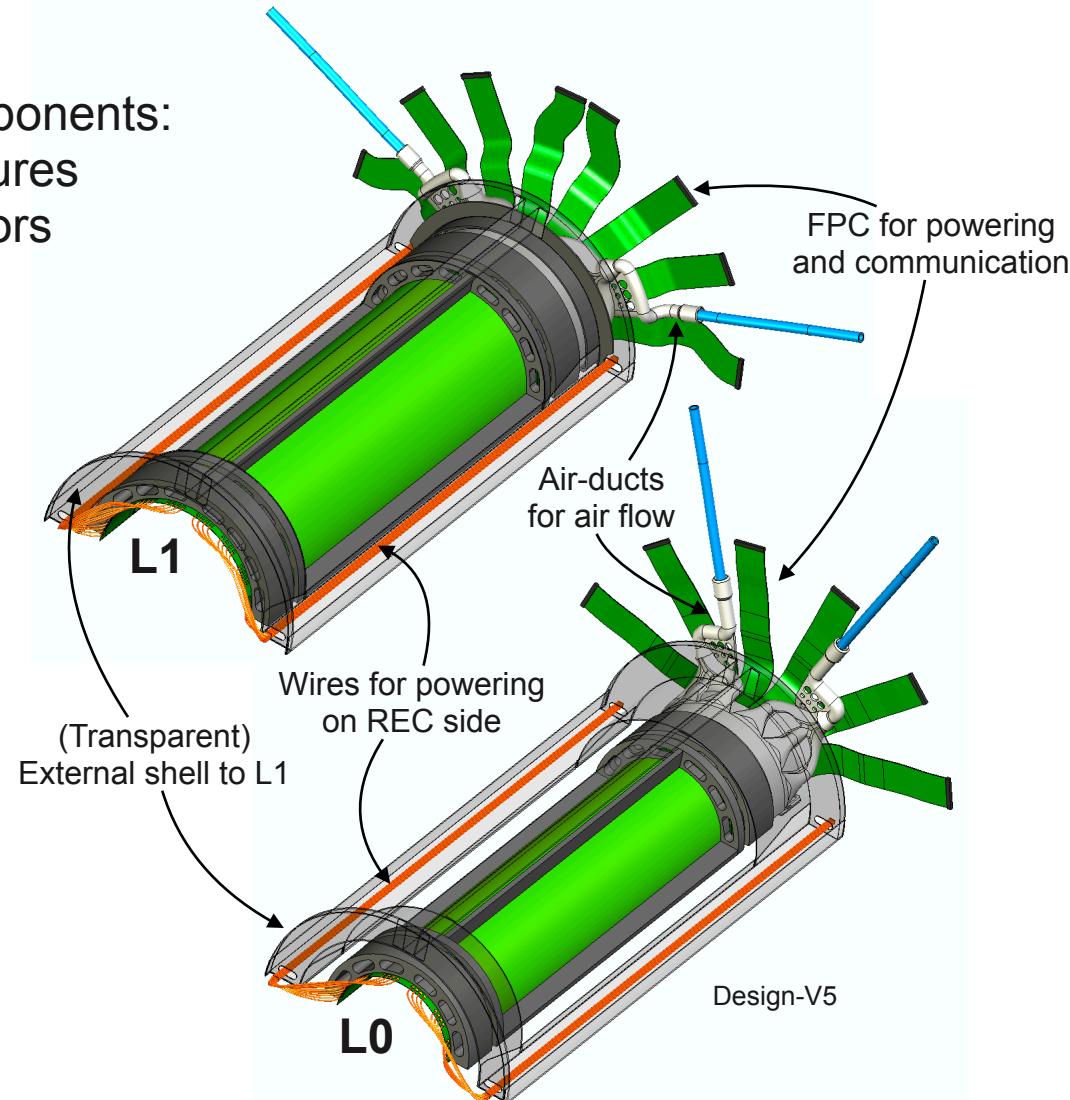
## L0-L1 half-barrel assembly procedure



Gluing of remaining components:

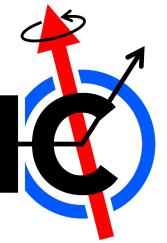
- FPC supporting structures
- Air-ducts and distributors
- Powering wires

Gluing tools same used  
for local support  
structures



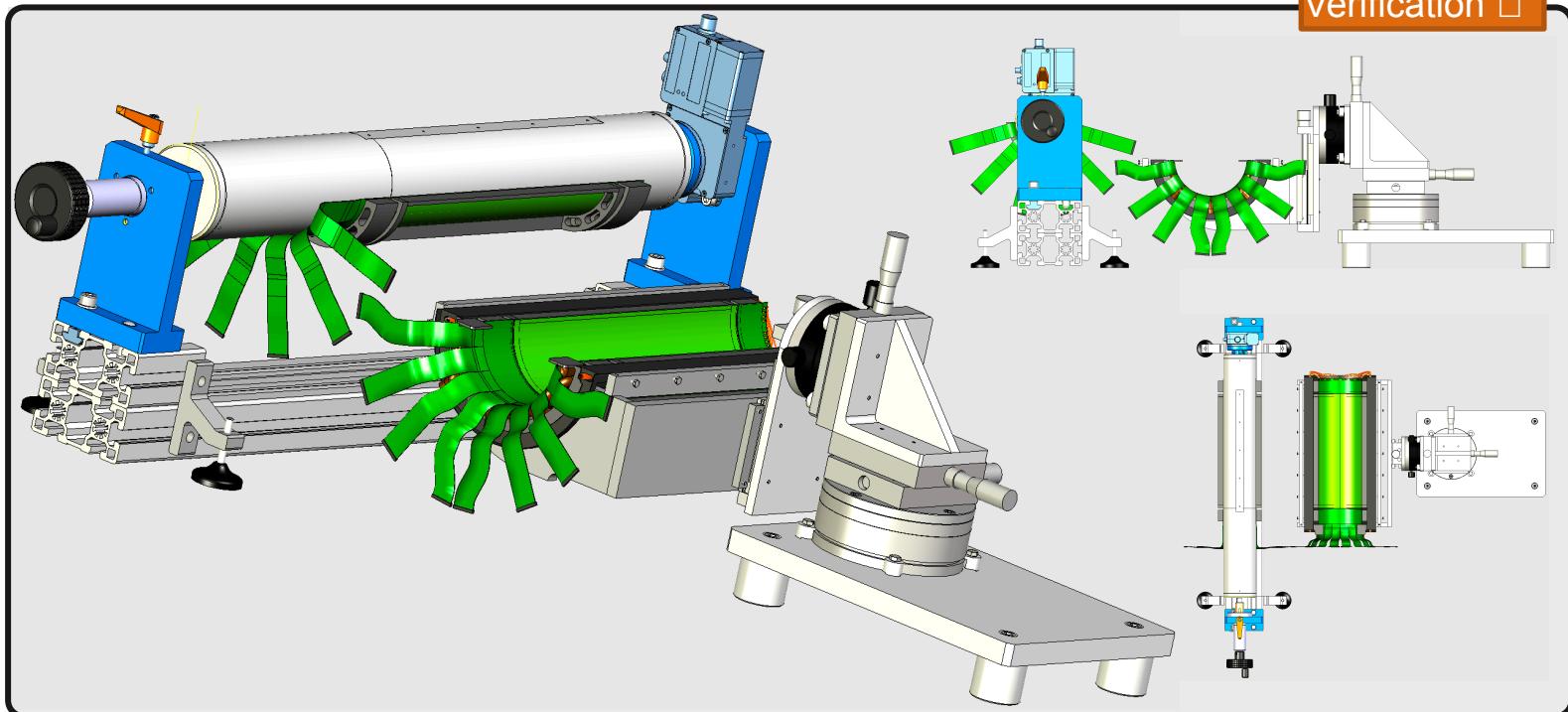
# Progress on SVT IB prototyping

## L0-L1 half-barrel assembly procedure



- Sensors alignment and joining ✓
- Joint sensors bending ✓
- FPC to sensors interconnection ⟳
- Local support structures gluing ⟳
- Services integration in layer ⟳
- L0-L1 half-barrel assembly ⟳

### Layer-to-layer or layer-to-shell gluing tool



# Progress on SVT IB prototyping

## L0-L1 layers and half-barrel prototyping campaign



Layer	Dates	BENDING	GLUING	REMOVAL
L0 <sub>v1</sub>	16/10/24-26/11/24	YES <small>Silicon chipping at one edge; located under the tape, allowed for bending</small>	YES	NO <small>Breakage due to previous damage</small>
L0 <sub>v2.1</sub>	13/01/25-14/01/25	NO <small>Breakage of one silicon edge possibly during the two sensors alignment</small>	—	—
L0 <sub>v2.2</sub>	16/01/25-31/01/25	YES	YES	YES
L0 <sub>v3</sub>	24/03/25-28/03/25	YES <small>Silicon broken already in the transport box</small>	NO <small>Breakage started from already present chipping</small>	—
L0 <sub>v4</sub>	03/04/25-10/04/25	YES	YES	YES
L0 <sub>v5</sub>	26/05/25-03/06/25	YES	YES	YES
L0 <sub>v7</sub>	08/10/25-27/10/25	YES <small>Silicon chipping at one corner during removal from transport box → Fixed with tape, allow for bending</small>	YES	YES
L1 <sub>v1</sub>	28/04/25-06/05/25	YES	NO <small>Operator error → Tools safety margins improved after failure</small>	—
L1 <sub>v2</sub>	07/07/25-09/07/25	YES	YES	YES
L1 <sub>v3</sub>	03/11/25-07/11/25	YES	YES	YES

Used for  
IB-HB01-M0

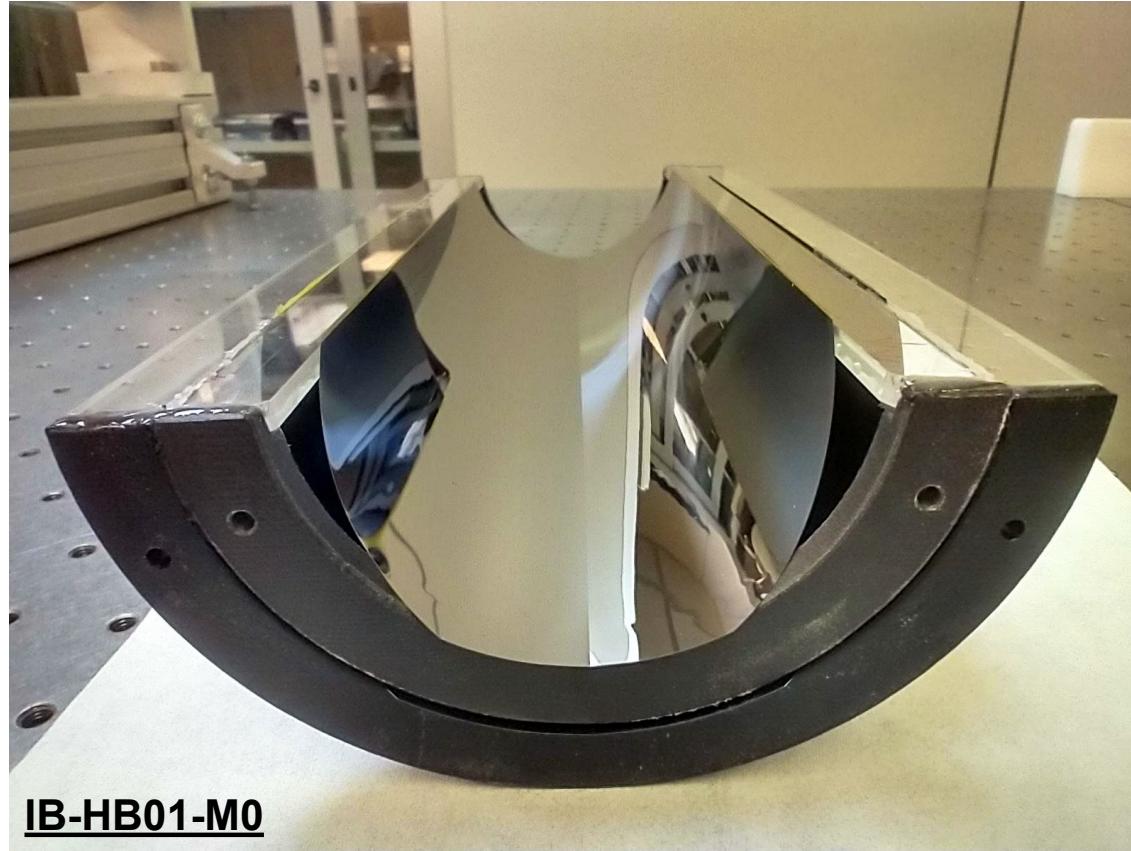
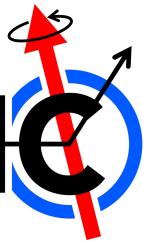
Used for  
IB-HB01-M1

Used for  
IB-HB01-M0

Used for  
IB-HB01-M1

# Progress on SVT IB prototyping

L0-L1 layers and half-barrel prototyping campaign



**IB-HB01-M0**

First L0-L1 bare half-barrel prototype



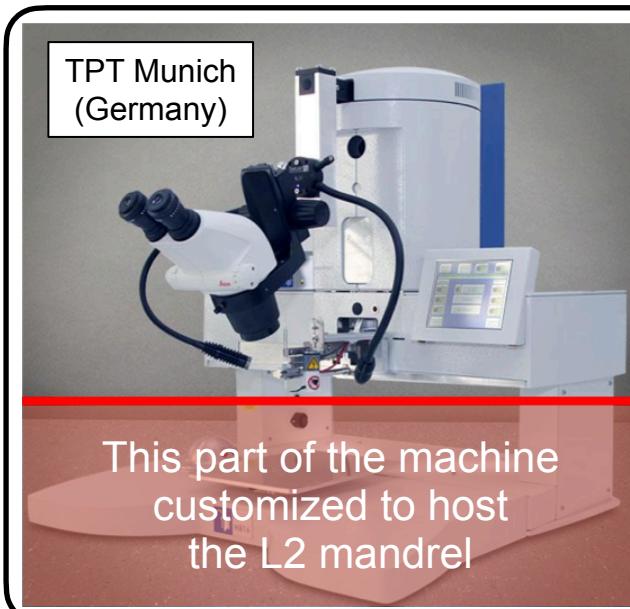
**IB-HB01-M1**

Second L0-L1 bare half-barrel prototype

- Requested/obtained support from ePIC INFN referees and nuclear physics committee (CSN3) to take the commitment to build L2 too (funding starting from 2026 budget)
- Bari and Padova will be the construction sites, interchangeable, more dedicated to L0-L1 the former, to L2 the latter

### Padova site preparation:

- Dedicated area in clean room for bending, wire-bonding, acceptance tests, etc.
- Another area dedicated to cooling tests, mock-up assembly (not requiring clean room)
- Bonding machine purchase speed-up anticipating funding from CSN3 in 2025 budget → Available before summer 2026.

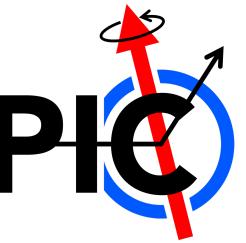


Wire wedge bonding machine

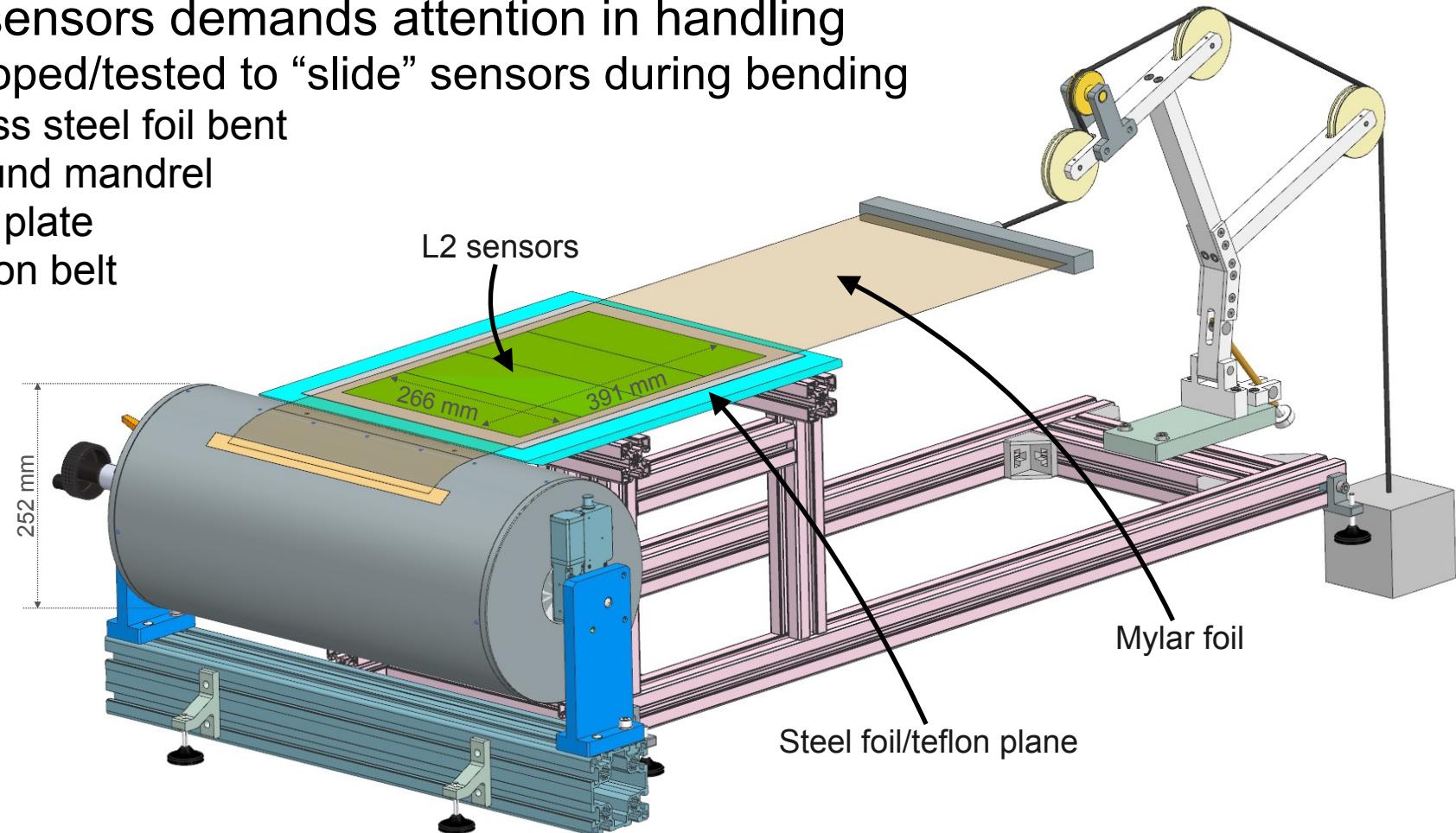
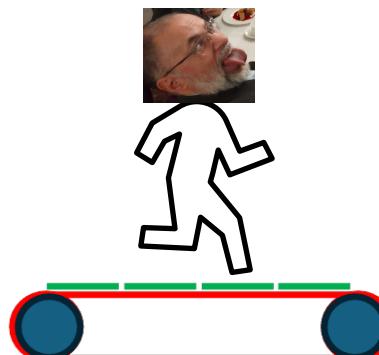
- purchase requisition completed, order out (today!)
- z, y movements will be integrated in the head (custom build)
- lower part (below red line) will be realized in Padova for custom mechanical acceptance, “from pin to elephant”
- delivery expected in 12 weeks from order

# Progress on SVT IB prototyping

## L2 half-layer assembly procedure



- Procedure for L2 assembly derived from L0+L1 experience
- Presence of four bigger sensors demands attention in handling
  - Few methods to be developed/tested to “slide” sensors during bending
    - Sensors stuck to a stainless steel foil bent together with sensors around mandrel
    - Sensors slipping on teflon plate
    - Sensors dragged on a teflon belt (“treadmill” method)



# Progress on SVT IB prototyping

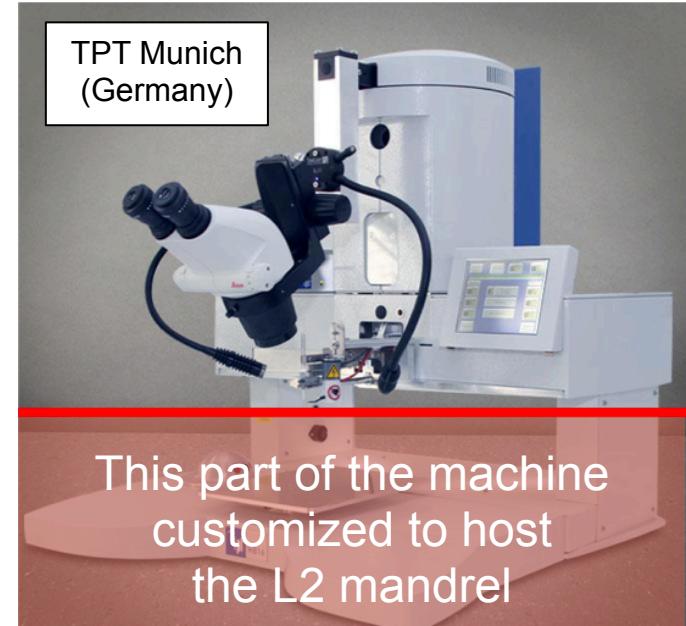
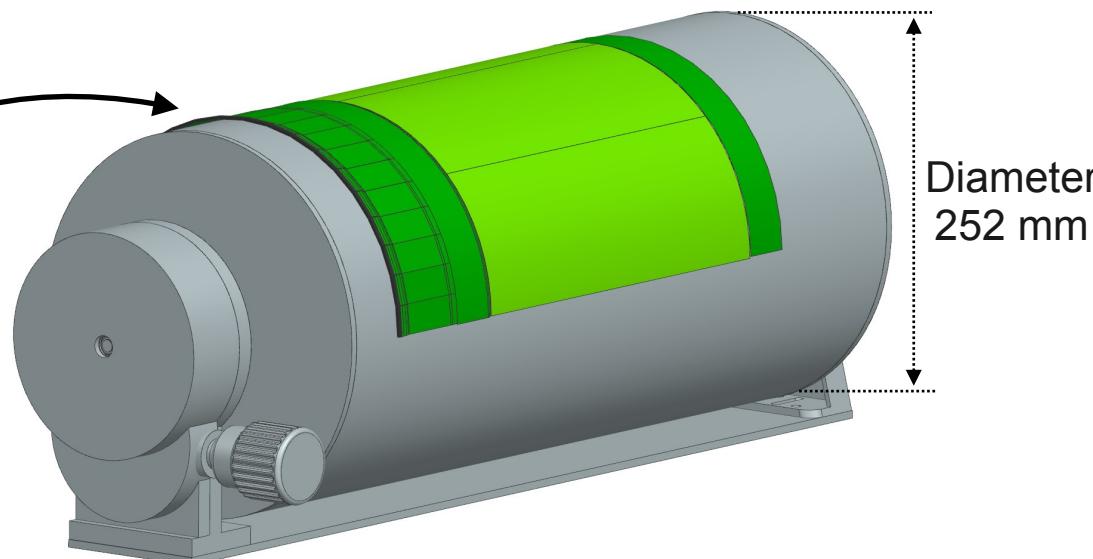
## L2 half-layer assembly procedure



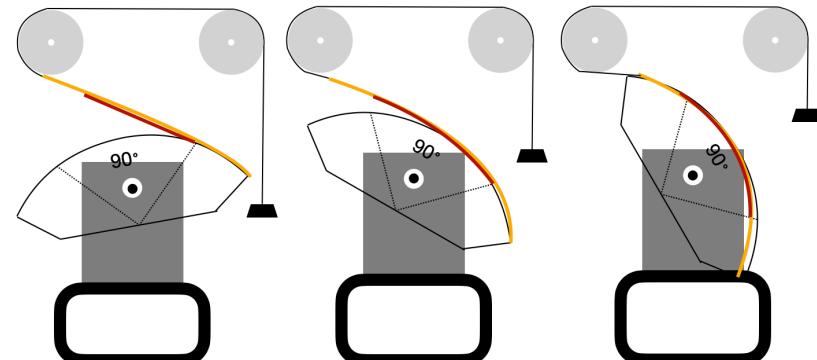
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3D printed mockup  
existing



- Procedure for L2 assembly derived from L0+L1 experience
- Presence of four bigger sensors demands attention in handling
  - Few methods to be developed/tested to “slide” sensors during bending
    - Sensors stuck to a stainless steel foil bent together with sensors around mandrel
    - Sensors slipping on teflon plate
    - Sensors dragged on a teflon belt (“treadmill” method)



- Alternative development, based on quarter layer modules, is required in Bari, where the maximum height available under the bonding machine is not enough to host the full L2 mandrel

# Progress on SVT IB prototyping

Activities during 2026 - L0-L1 half-barrel prototyping campaign and material procurement



Prototype	Components	Goal	Target date
<b>IB-HB01-M1</b>	<ul style="list-style-type: none"> <li>• 2+2 silicon L0+L1 <b>naked sensors</b> → AVAILABLE</li> <li>• L0+L1 local support structures 3D printed → AVAILABLE</li> </ul>	Finalize half-layer assembly procedure	<b>Completed by November 2025</b>
<b>IB-HB01-M2</b>	<ul style="list-style-type: none"> <li>• 2+2 silicon L0+L1 <b>naked sensors</b> → AVAILABLE</li> <li>• L0+L1 local support structures in carbon foam (only ERG) → RAW MATERIAL PROCURED</li> <li>• Outer support shell to L1 in carbon fibre → UNDER PRODUCTION</li> </ul>	Mechanical stress studies in climate chamber	To be completed by January 2026
<b>IB-HB01-M3</b>	<ul style="list-style-type: none"> <li>• 2+2 silicon L0+L1 <b>sensors with heaters</b> → AVAILABLE</li> <li>• L0+L1 local support structures in carbon foam (both ERG and Allcomp) → PARTIALLY PROCURED</li> <li>• L0+L1 air-ducts → TO BE PRINTED</li> <li>• Outer support shell to L1 3D printed → TO BE PRINTED</li> </ul>	First full integration and studies of the cooling effectiveness in wind tunnel	To be completed by March 2026
<b>IB-HB012-M1</b>	<ul style="list-style-type: none"> <li>• 2+2(+4) <b>ER2 pad L0+L1(+L2) sensors</b></li> <li>• L0+L1+L2 local support structures in carbon foam (both ERG and Allcomp)</li> <li>• L0+L1+L2 FPCs</li> <li>• L0+L1+L2 air-ducts</li> <li>• Outer support shell to L1 and to L2 3d printed</li> <li>• IB global support mechanics 3d printed</li> </ul>	<ul style="list-style-type: none"> <li>• First compete integration including wire-bonding</li> <li>• Possible assembly of 2 HBs to allow mechanical matching</li> </ul>	To be completed by July 2026
<b>IB-HB012-M2</b>	<ul style="list-style-type: none"> <li>• 2+2(+4) <b>ER2 L0+L1(+L2) sensors</b></li> <li>• L0+L1+L2 local support structures in carbon foam (both ERG and Allcomp)</li> <li>• L0+L1+L2 FPCs</li> <li>• L0+L1+L2 air-ducts</li> <li>• Outer support shell to L1 and to L2 in carbon fiber</li> <li>• IB global support mechanics 3d printed</li> </ul>	<ul style="list-style-type: none"> <li>• Qualification model integrating actual sensors for full system (cooling, powering, DAQ, DCS) characterization</li> </ul>	To be completed by October 2026

# Progress on SVT IB prototyping

Activities during 2026 - L2 setup preparation and initial prototyping

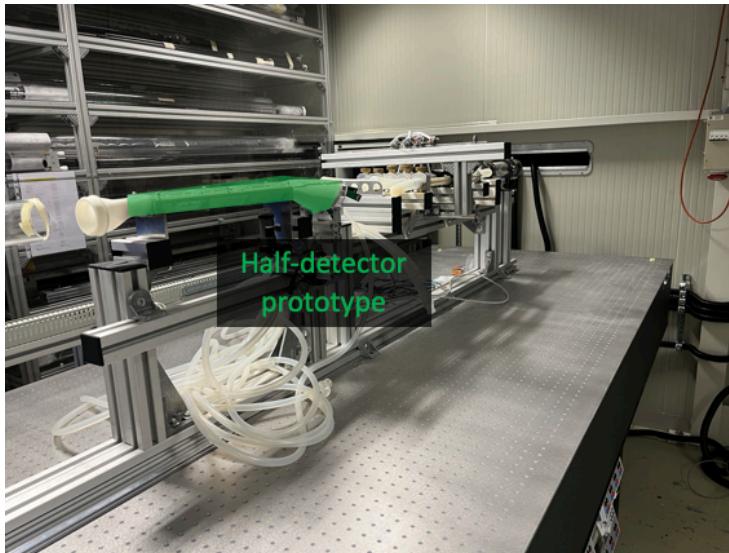


- Design of tooling for L2 assembly → Mostly adapted from L0-L1 tools
  - Sensors alignment and joining tool
  - Bending/bonding tool
  - Local support structures gluing tool
  - L2 external shell gluing tool
- Setup for L2 bending
  - Starting with mockup parts
  - Targeting first exercise with naked silicon pieces after summer
- Setup for thermal study → More in Chiara Bonini's presentation later
  - Initially in flat configuration
  - Final detector configuration (integrated with IB-HB01-M3) in a wind tunnel, suitable also for vibrational studies / comparison with FEA simulations

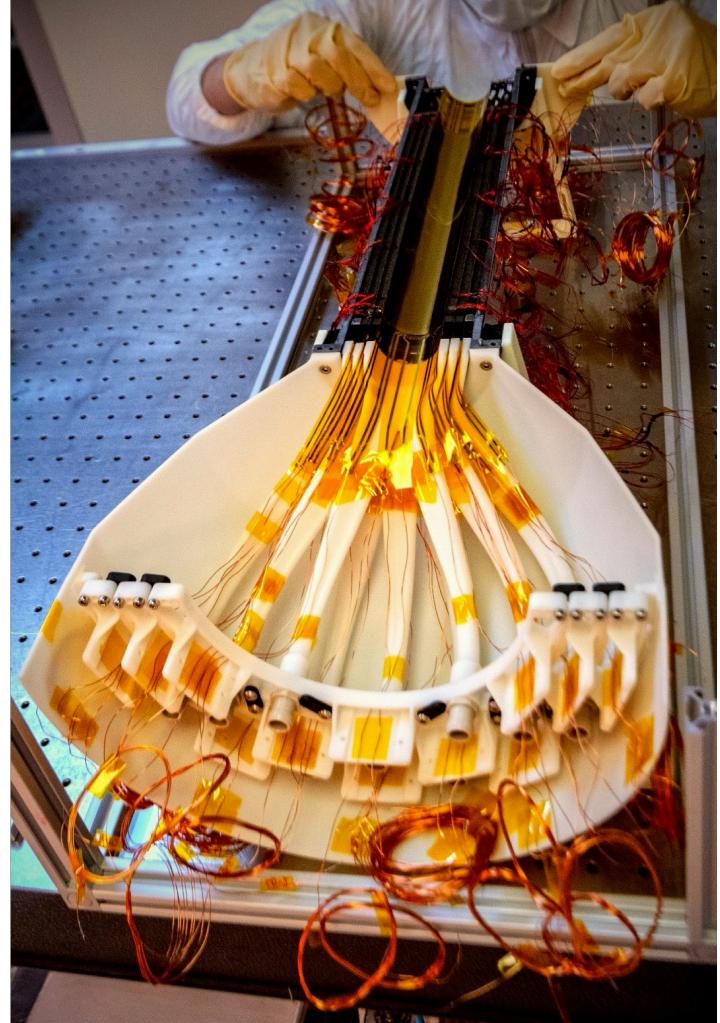
- L0-L1 assembly procedure in advanced status
  - Tooling development almost completed and production ongoing in Bari
- L2 assembly procedure at its first steps
  - Lot of effort expected in Padova in the first part of 2026
- Prototyping campaign advancing according to schedule
  - Targeting prototypes for specific measurements (mechanical stress, cooling effectiveness, aging test) until mid of 2026 (before arrival of MOSAIX sensors)
  - Final integration and verification campaign using MOSAIX sensors
- Material procurement progressing
  - Possible issue with K9 Allcomp carbon foam (for LEC cooling)
    - Proposed joint procurement with larger collaborations or alternative material



- Dedicated prototype IBL01\_P5 (> January 2026)
  - L0 and L1 heaters
  - Proper carbon foam or alternatives
  - Air-ducts and temperature sensors (PT1000)
- Wind tunnel setup
  - Investigating where to assemble it
  - going to investigate (also within SVT DSC) for possible help, both for infrastructure and person-power

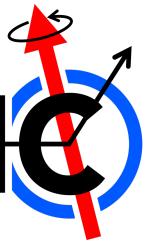


ITS3 wind tunnel @CERN



ITS3 BBM6 prototype

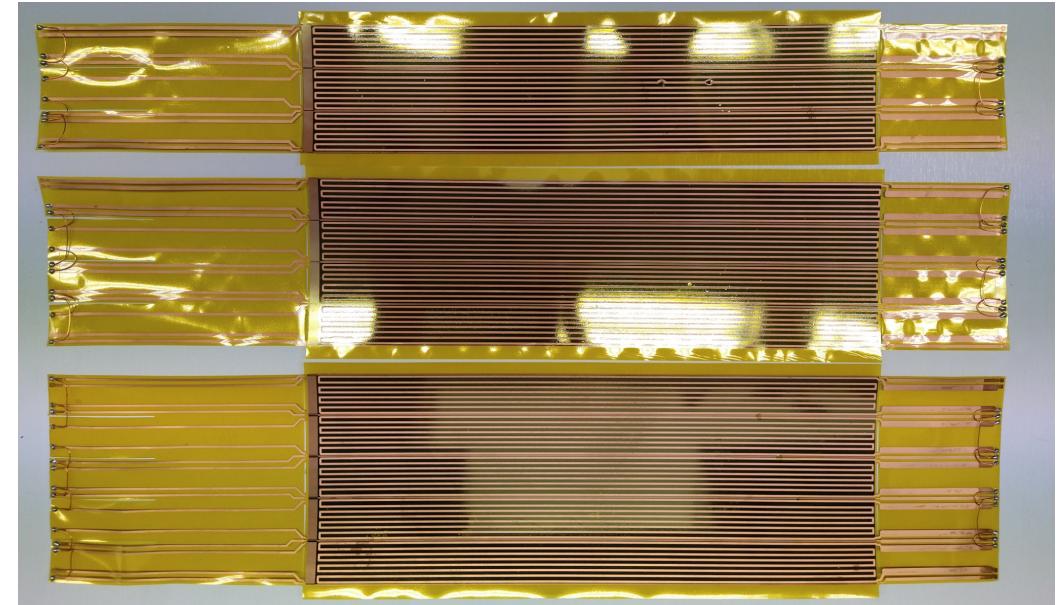
# Progress on SVT IB prototyping



Silicon pieces	4 L0 - 4 L1	AVAILABLE	Spares under procurement
Heaters	2 L0 - 2 L1	AVAILABLE	Spares: 2 L0 / 2 L1
Pad sensors	[ 2 L0 - 2 L1 - (4 L2) ] x 2	2026	If two HB (16 pad sensors = 16 wafers) → No spares
ER2 sensors	2 L0 - 2 L1 - (4 L2)	2026	Only one half-barrel → No spares

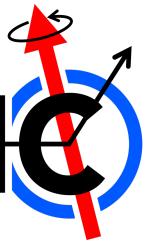


Blank silicon pieces of exact L0 and L1 sizes

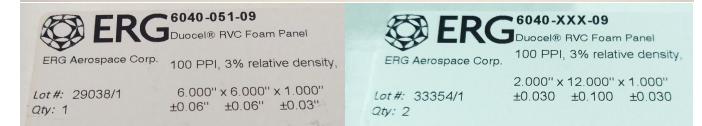
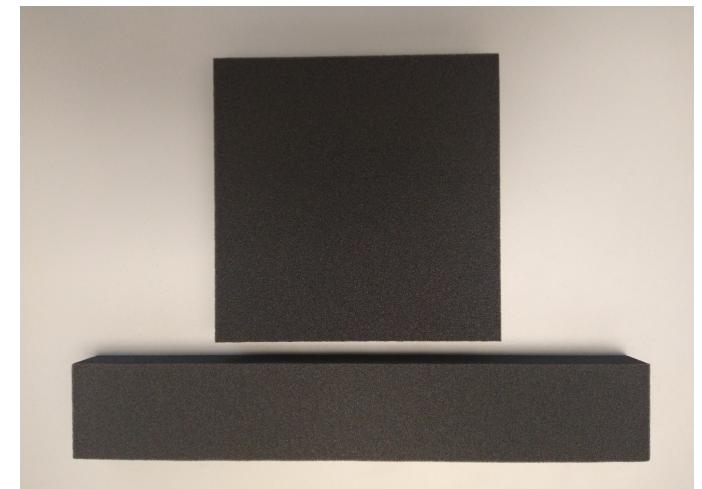


Heaters integrating blank silicon

# Progress on SVT IB prototyping



3D printed	Mixing printed and manufactured in very first exercises
Carbon fibre/foam	<p><u>Material for support structure elements</u></p> <ul style="list-style-type: none"><li>• Half-ring on LEC → Allcomp K9 (standard density, 200-260 kg/m<sup>3</sup>)</li><li>• Longerons and half-ring on REC → Carbon RVC Duocel (density 45 kg/m<sup>3</sup>, PPI 100)</li><li>• Carbon fleece: wet-laid non woven carbon fibre veil(8 g/cm<sup>2</sup>)</li><li>• Outer shell: carbon fibre (from global structure)</li></ul> <p><u>Foam procurement</u></p> <ul style="list-style-type: none"><li>• Allcomp K9 → Not easy to procure in small amount; try to associate with large request (e.g. ATLAS)</li><li>• ERG Carbon RVC Duocel → Purchasing from USA + Receiving samples from alternative producer</li></ul> <p><u>Foam shaping</u></p> <ul style="list-style-type: none"><li>• Procedure details collected from CERN colleagues</li><li>• Ongoing at Genova INFN → First example completed (in POCOfoam)</li><li>• Berkley (Nikki) or U.K. (George) → Expressed availability</li><li>• Local workshop → To be identified</li></ul> <p><u>Carbon fibre production</u></p> <ul style="list-style-type: none"><li>• Multiple-producers under investigation (Padova)</li></ul>



First samples of ERG Carbon RVC Duocel.  
Thanks to Nikki!

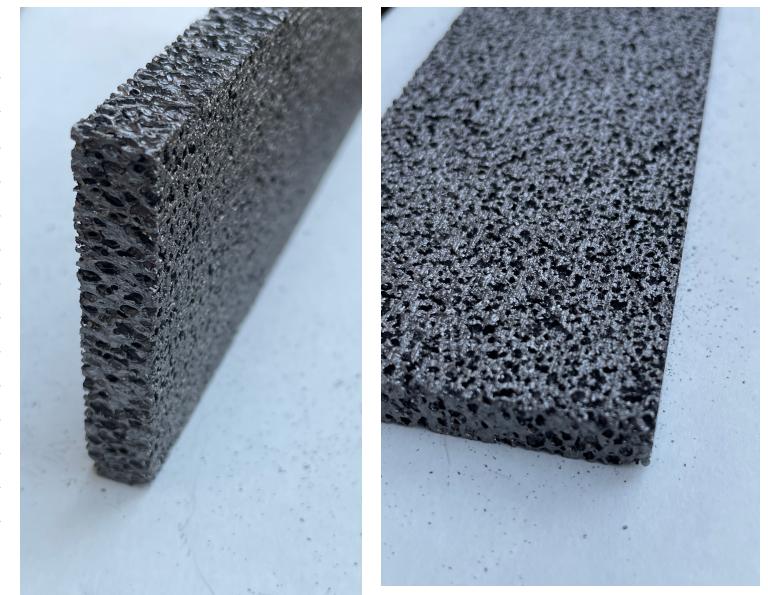
Material sent to Genova for machining

# Progress on SVT IB prototyping

New carbon foam from [CFOAM](#), West Virginia (USA): HTC (stands for High Thermal Conductivity)

- easy to procure
- high thermal conductivity (to be verified, in touch with CNR and Engineering Department in Padova; a private company a true alternative)
- really dusty ☺ - need for a cleaning procedure, or painting → to be verified also under mechanical stress
- tested at CERN some time ago, will check the outcome...

Property	units	CFOAM HTC	ERG Duocel	Allcomp K9
		value	value	value
Nominal Density	g/cc	0.4 – 0.6	0.045	0.36-0.22
Compressive Strength	MPa	1.5 – 1.8	0.10-0.52	70-35 approx (resp. for the two densities)
Compressive Modulus	MPa	100 – 400		
Tensile Strength	MPa	0.9 – 1.0	0.17-0.34	
Shear Strength	MPa	1.0 – 4.0	30.3	
Coefficient of Thermal Expansion	ppm/°C	2	2.2	
Thermal Conductivity	W/m-K	106 at 0.47 g/cc	0.033-0.05	64
Maximum Operational Use Temperature	°C	400	315	
Electrical Resistivity	milliohm-cm	3 – 4	323	
Pore Volume	%	>70%	97%	
Mean Pore Size	Microns	1,200	254-5080 available	130 ppi, or 3907 micron mean size



## Sensors alignment and joining

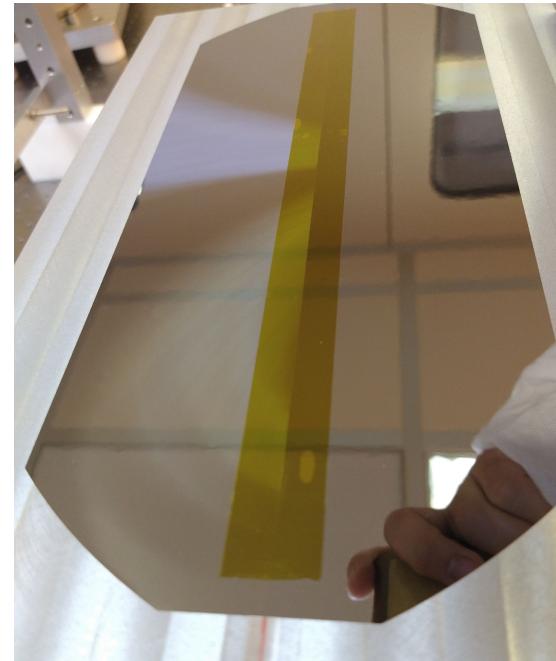
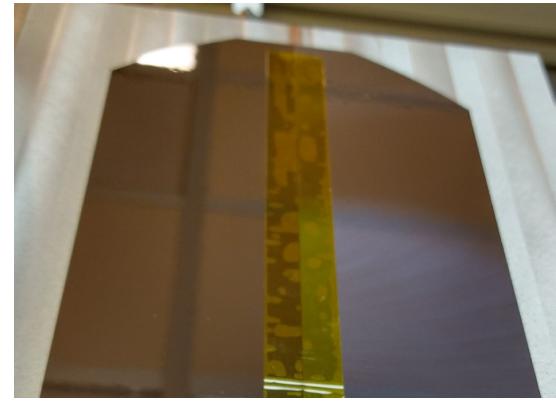


Parallelism has higher priority than pitch minimization since a large tilt can affect the success of the bondings to FPC.

#	ID	Average pitch ( $\mu\text{m}$ )	Tilt angle ( $^\circ$ )
1	<b>L0v1</b>	150	$\pm 0.021$
2	<b>L0v2</b>	285	$\pm 0.008$
3	<b>L0v3</b>	144	$\pm 0.006$
4	<b>L0v4</b>	141	$\pm 0.002$
5	<b>L1v1</b>	75.5	$\pm 0.0014$
6	<b>L0v5</b>	<b>51.5</b>	$\pm 0.0004^*$

- + Offline measurements by analysing pictures
- + Design of accessories to reduce the number of attempts to reach the desired tilt and pitch.

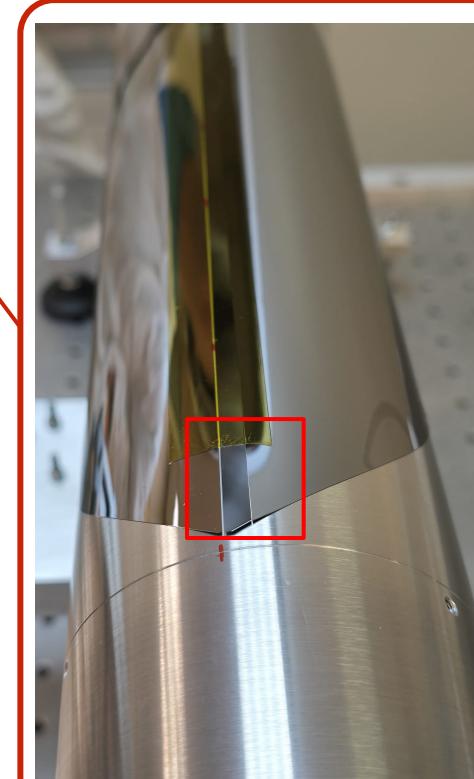
\*tilt under the resolution of dinoscope



Negligible cusps are observed after the bending

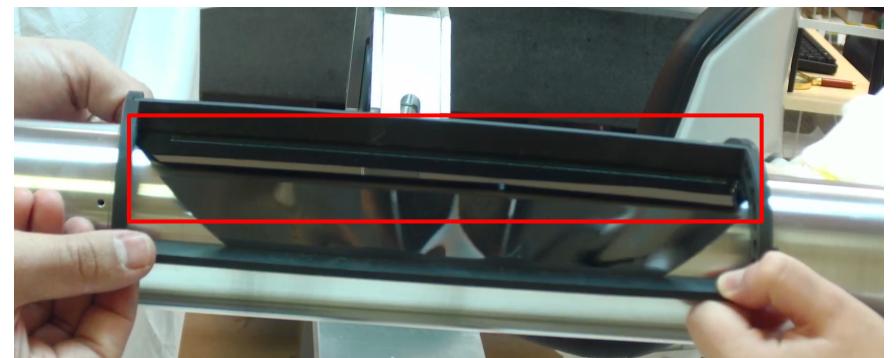
# Progress on SVT IB prototyping

Layer	Dates	BENDING	GLUING	REMOVAL
L0v1	16/10/24-26/11/24	YES <small>Silicon chipping at one edge, located under the tape, allowed for bonding</small>	YES	NO <small>Breakage due to previous damage</small>
L0v2.1	13/01/25-14/01/25	NO <small>Breakage of one silicon edge possibly during the two sensors alignment</small>	—	—
L0v2.2	16/01/25-31/01/25	YES	YES	YES
L0v3	24/03/25-28/03/25	YES <small>Silicon broken already in the transport box</small>	NO <small>Breakage started from already present chipping</small>	—
L0v4	03/04/25-10/04/25	YES	YES	YES
L0v5	26/05/25-03/06/25	YES	YES	YES
L0v7	08/10/25-27/10/25	YES <small>Silicon chipping at one corner during removal from transport box → Fixed with tape, allow for bending</small>	YES	YES
L1v1	28/04/25-06/05/25	YES	NO <small>Operator error → Tools safety margins improved after failure</small>	—
L1v2	07/07/25-09/07/25	YES	YES	YES
L1v3	03/11/25-07/11/25	YES	YES	YES



Silicon breakage located under the tape, still allowed the bending

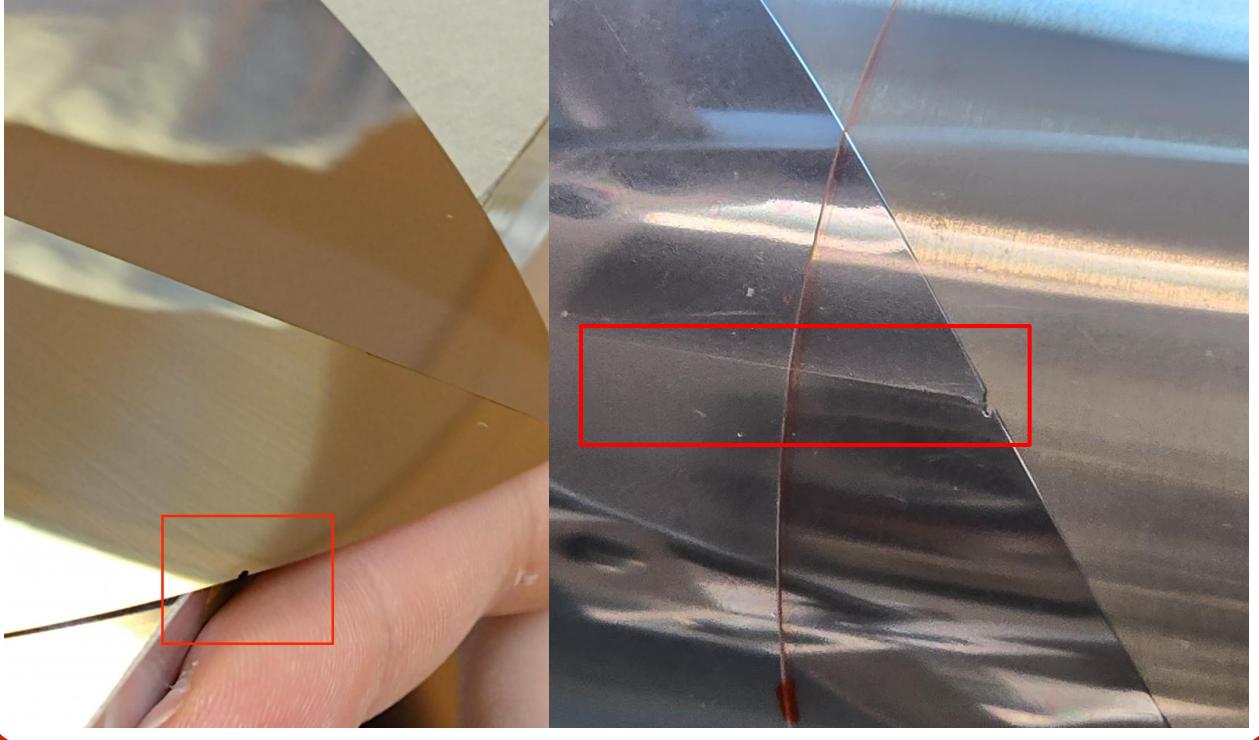
Final breakage during removal from mandrel



# Progress on SVT IB prototyping

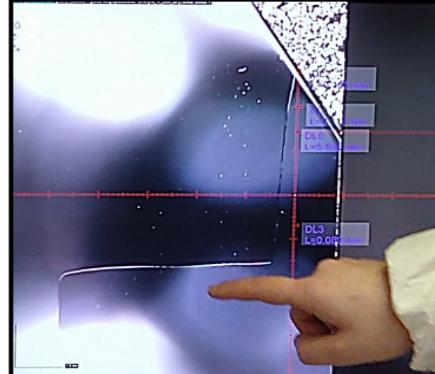
Layer	Dates	BENDING	GLUING	REMOVAL
L0v1	16/10/24-26/11/24	YES <small>Silicon chipping at one edge, located under the tape, allowed for bonding</small>	YES	NO <small>Breakage due to previous damage</small>
L0v2.1	13/01/25-14/01/25	NO <small>Breakage of one silicon edge possibly during the two sensors alignment</small>	—	—
L0v2.2	16/01/25-31/01/25	YES	YES	YES
L0v3	24/03/25-28/03/25	YES <small>Silicon broken already in the transport box</small>	NO <small>Breakage started from already present chipping</small>	—
L0v4	03/04/25-10/04/25	YES	YES	YES
L0v5	26/05/25-03/06/25	YES	YES	YES
L0v7	08/10/25-27/10/25	YES <small>Silicon chipping at one corner during removal from transport box → Fixed with tape, allow for bonding</small>	YES	YES
L1v1	28/04/25-06/05/25	YES	NO <small>Operator error → Tools safety margins improved after failure</small>	—
L1v2	07/07/25-09/07/25	YES	YES	YES
L1v3	03/11/25-07/11/25	YES	YES	YES

The edge defect caused the break during the bending



# Progress on SVT IB prototyping

Layer	Dates	BENDING	GLUING	REMOVAL
L0v1	16/10/24-26/11/24	YES <small>Silicon chipping at one edge, located under the tape, allowed for bonding</small>	YES	NO <small>Breakage due to previous damage</small>
L0v2.1	13/01/25-14/01/25	NO <small>Breakage of one silicon edge possibly during the two sensors alignment</small>	—	—
L0v2.2	16/01/25-31/01/25	YES	YES	YES
L0v3	24/03/25-28/03/25	YES <small>Silicon broken already in the transport box</small>	NO <small>Breakage started from already present chipping</small>	—
L0v4	03/04/25-10/04/25	YES	YES	YES
L0v5	26/05/25-03/06/25	YES	YES	YES
L0v7	08/10/25-27/10/25	YES <small>Silicon chipping at one corner during removal from transport box → Fixed with tape, allow for bending</small>	YES	YES
L1v1	28/04/25-06/05/25	YES <small>Operator error → Tools safety margins improved after failure</small>	NO	—
L1v2	07/07/25-09/07/25	YES	YES	YES
L1v3	03/11/25-07/11/25	YES	YES	YES



Crack stopped during bending procedures using microscope (not easily visible by eye).

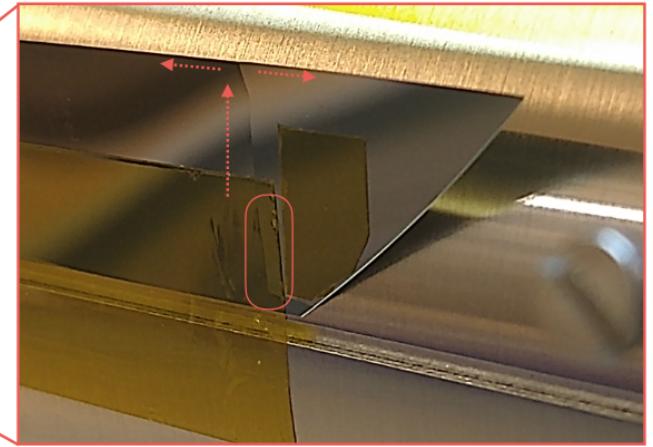


Broken silicon pipe found in the same box

- Don't stack many silicones in the same box
- Visual inspection before each assembly

**Discovered fracture was covered by extra kapton tape**



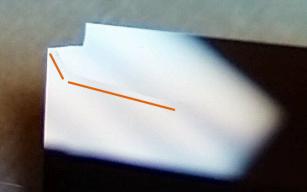


Extra tape was not sufficient: fracture was the source of the successive break in the picture

# Progress on SVT IB prototyping

Layer	Dates	BENDING	GLUING	REMOVAL
L0v1	16/10/24-26/11/24	YES <small>Silicon chipping at one edge, located under the tape, allowed for bonding</small>	YES	NO <small>Breakage due to previous damage</small>
L0v2.1	13/01/25-14/01/25	NO <small>Breakage of one silicon edge possibly during the two sensors alignment</small>	—	—
L0v2.2	16/01/25-31/01/25	YES	YES	YES
L0v3	24/03/25-28/03/25	YES <small>Silicon broken already in the transport box</small>	NO <small>Breakage started from already present chipping</small>	—
L0v4	03/04/25-10/04/25	YES	YES	YES
L0v5	26/05/25-03/06/25	YES	YES	YES
L0v7	08/10/25-27/10/25	YES <small>Silicon chipping at one corner during removal from transport box → Fixed with tape, allow for bonding</small>	YES	YES
L1v1	28/04/25-06/05/25	YES	NO <small>Operator error → Tools safety margins improved after failure</small>	—
L1v2	07/07/25-09/07/25	YES	YES	YES
L1v3	03/11/25-07/11/25	YES	YES	YES

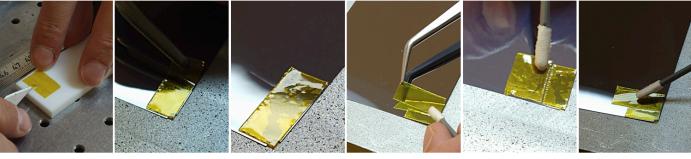
**8/10/2025**  
Breakage of one corner of one silicon piece while picking from the box → Look for larger boxes



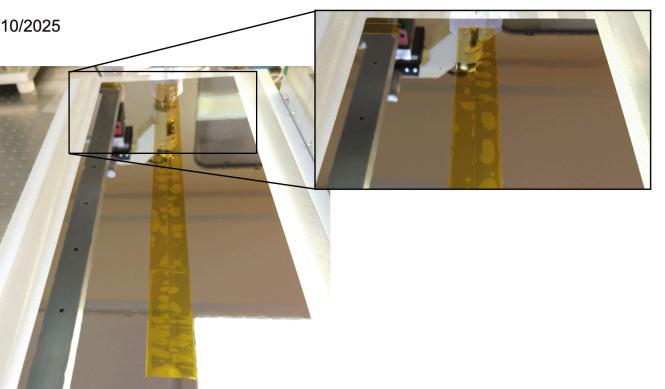
Silicon pieces temporary put aside and alignment/joining completed with a third silicon pieces → Later decided to keep this double silicon pieces for the HBM2.

Next day, fixing broken piece and aligned/joined to the fourth silicon piece.

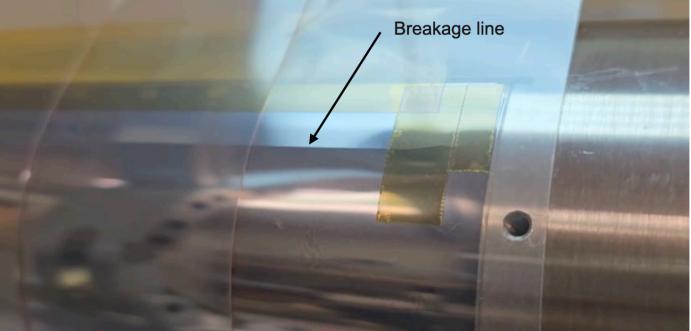
**9/10/2025**  
Adhesive tape application on both sides of the silicon piece to cover and "contain" the crack.



**9/10/2025**



**10/10/2025**



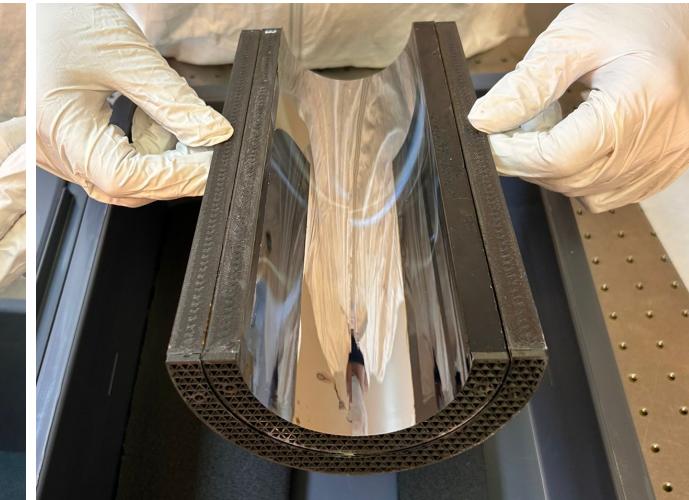
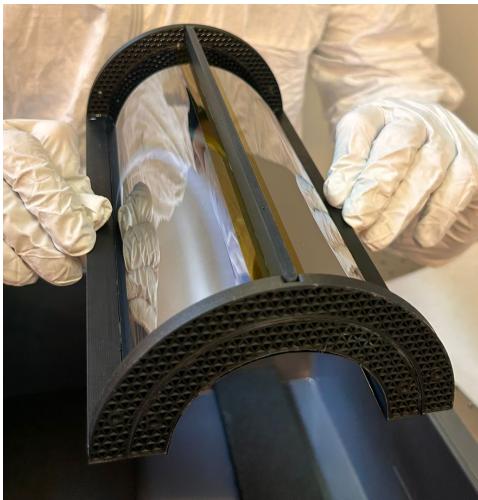
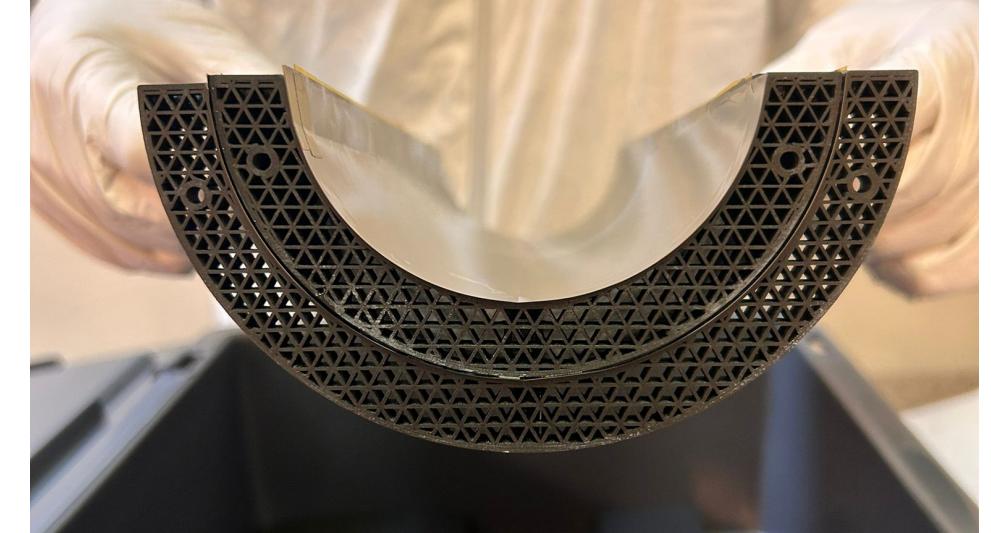
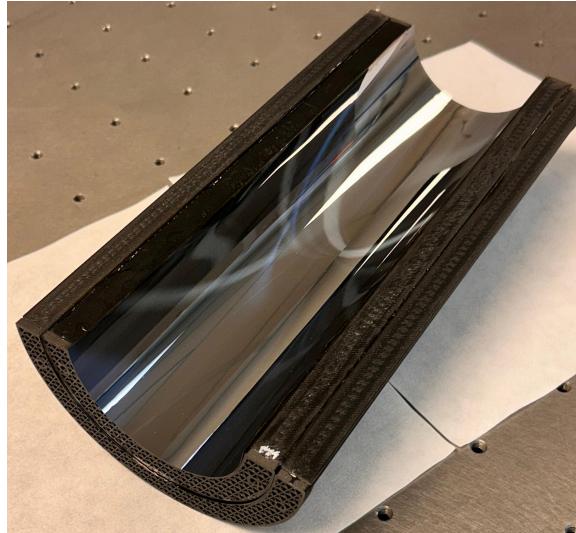
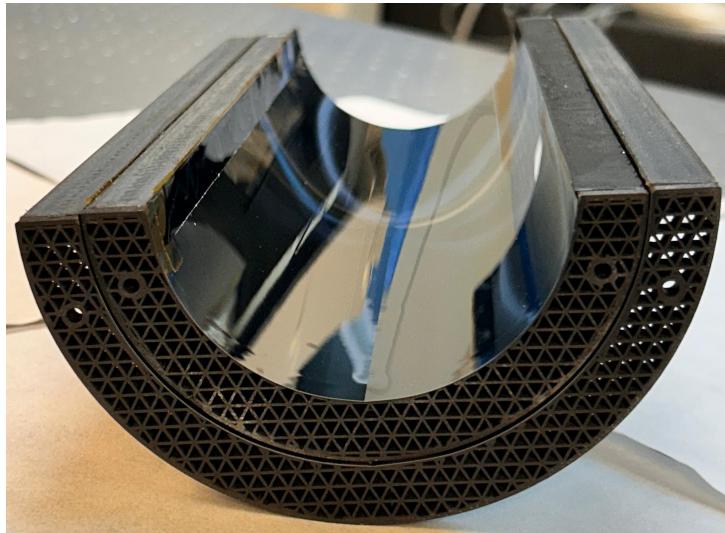
**27/10/2025**



L0: try to recover the broken silicon couple to complete the HBM1 assembly (without using the limited available spares).  
L1: use the two available full size silicon pieces.

# Progress on SVT IB prototyping

## IB-HB01-M1





## IB prototyping activity

### Prototyping in 2026 with ER2 (pad) wafer:

- what is going to be available for SVT:
  - ✓ **24 ER2 pad wafers** (w/ pads w/o sensor)
  - ✓ **12 ER2 wafers** (w/ pads & sensor)
- IB HB prototype with ER2 pad wafers:
  - ✓ full proto (including FPCs) suited for mechanical tests
  - ✓ min required pieces (not considering failures/breakings):
    - 2 x 3 segments + 2 x 4 segments + 4 x 5 segments = **8 pad wafers**
    - ideally 2 HBs (mechanical matching tests) → 2 x 8 = **16 pad wafers** with given segments distribution
- IB HB prototype with ER2 wafers:
  - ✓ full proto (including FPCs) suited for mechanical/cooling/electrical post-assembly tests
  - ✓ suitable also for powering/DAQ/DCS development on close-to-final setup system
  - ✓ min required pieces (not considering failures/breakings and sensor yield): **8 wafers**

